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Machine learning generalised DFT+U projectors in a numerical atom-centred orbital framework

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Accurate electronic structure simulations of strongly correlated metal oxides are crucial for the atomic level understanding of heterogeneous catalysts, batteries and photovoltaics, but remain challenging to perform in a computationally tractable manner. Hubbard corrected density functional theory (DFT+U) in a numerical atom-centred orbital framework has been shown to address this challenge but is susceptible to numerical instability when simulating common transition metal oxides (TMOs), *e.g.*, TiO_2 and rare-earth metal oxides (REOs), *e.g.*, CeO_2 , necessitating the development of advanced DFT+U parameterisation strategies. In this work, the numerical instabilities of DFT+U are traced to the default atomic Hubbard projector, which we refine for Ti 3d orbitals in TiO_2 using Bayesian optimisation, with a cost function and constraints defined using symbolic regression (SR) and support vector machines, respectively. The optimised Ti 3d Hubbard projector enables the numerically stable simulation of electron polarons at intrinsic and extrinsic defects in both anatase and rutile TiO_2 , with comparable accuracy to hybrid-DFT at several orders of magnitude lower computational cost. We extend the method by defining a general first-principles approach for optimising Hubbard projectors, based on reproducing orbital occupancies calculated using hybrid-DFT. Using a hierarchical SR-defined cost function that depends on DFT-predicted orbital occupancies, basis set parameters and atomic material descriptors, a generalised workflow for the one-shot computation of Hubbard U values and projectors is presented. The method transferability is shown for 10 prototypical TMOs and REOs, with demonstrable accuracy for unseen materials that extends to complex battery cathode materials like $\text{LiCo}_{1-x}\text{Mg}_x\text{O}_{2-x}$. The work highlights the integration of advanced machine learning algorithms to develop cost-effective and transferable workflows for DFT+U parameterisation, enabling more accurate and efficient simulations of strongly correlated metal oxides.

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1 Introduction

A knowledge of the electronic structure of transition metal oxides (TMOs) and rare-earth metal oxides (REOs) is essential for the development of energy materials for net zero. For example, TMOs and REOs are widely used as support materials in heterogeneous catalysis to enhance the reactivity of metal nanoparticles *via* the formation of catalytically active electron traps (*i.e.*, electron polarons) at interfacial and defect sites. By controlling the formation of electron polarons, catalytic activity and selectivity can be tuned to achieve controllable CO_2 conversion using CeO_2 -based catalysts,¹ H_2 production using MoO_3 -based catalysts² and the production of sustainable aviation fuel *via* the Fischer Tropsch process using TiO_2 -based catalysts.³ TMOs and REOs are also widely applicable for technologies in the generation and storage of electricity, due to the ability to tune the mobility of electrons and ions. Tuneable charge carrier mobility can be exploited for the development of photovoltaics and lithium ion battery cathodes using dopants

such as Nb and Mg to optimise the electrical performance of TiO_2 and LiCoO_2 , respectively.^{4,5}

Despite extensive experimental research across a broad range of TMO- and REO-based energy materials, realising a step change in their design and optimisation requires first-principles simulation methods, such as density functional theory (DFT),^{6,7} to bridge theory and experiment; however, accurate DFT simulations of the ground state electronic structures of TMOs and REOs can be very challenging. The self-interaction error (SIE), which arises when using local and semi-local exchange-correlation density functionals to describe the correlation between electrons occupying localised d or f orbitals, results in electronic repulsion that causes systematic errors in predicted material properties, *e.g.*, underestimated insulator band gaps, inaccurate lattice parameters and inaccurate formation energies of point defects and electron polarons.^{8–10} To overcome the limitations of DFT for strongly correlated materials, “beyond-DFT” methods can be applied that add corrective schemes to combat the SIE. Hubbard corrected density functional theory (DFT+U) is a suitable and popular beyond-DFT method, involving a tuneable on-site Coulomb repulsion, *i.e.*, an energy penalty against electron

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delocalisation that is applied selectively to correlated orbitals in the system.¹¹ DFT+*U* is popular because it adds minimal computational cost compared to standalone DFT,¹² whilst achieving the accuracy of higher levels of theory such as hybrid-DFT if parameterised carefully.¹³

To accurately parameterise DFT+*U*, one must account for both the magnitude and basis of the Hubbard correction, which are defined using the Hubbard *U* value and the Hubbard projector function (or Hubbard projector) respectively. These parameters are used to correct the DFT-predicted total energy (E_{DFT}) with a corrective Hubbard term that treats localised states only (E_U^0) and a double counting correction (E_U^{dc}) that prevents the double counting of localised states in both E_{DFT} and E_U^0 :

$$E_{\text{DFT}+U}[\rho(\mathbf{r}), \mathbf{n}_{I,m}^{\sigma}] = E_{\text{DFT}}[\rho(\mathbf{r})] + E_U^0[\mathbf{n}_{I,m}^{\sigma}] - E_U^{\text{dc}}[\mathbf{n}_{I,m}^{\sigma}] \quad (1)$$

where $\rho(\mathbf{r})$ is the electron density and $\mathbf{n}_{I,m}^{\sigma}$ is the occupation matrix, whose diagonal elements correspond to orbital occupation numbers for all atoms (*I*), orbital magnetic quantum numbers (*m*) and spin channels (σ). According to the rotationally invariant, spherically averaged implementation proposed by Dudarev *et al.*,¹⁴ the corrective Hubbard term is calculated using the trace (Tr) of the occupation matrix and its square:

$$E_U^0[\mathbf{n}_{I,m}^{\sigma}] = \sum_{(\sigma, I)} U^I [\text{Tr}(\mathbf{n}_{I,m}^{\sigma}) - \text{Tr}(\mathbf{n}_{I,m}^{\sigma} \mathbf{n}_{I,m}^{\sigma})] \quad (2)$$

The occupation matrix is calculated by projecting all DFT-predicted Kohn-Sham states onto reference orbitals defined by the Hubbard projector, *i.e.*, calculating the overlap between Kohn-Sham states and spatially localised orbitals, before an overlap-dependent assignment of the occupancy of each Kohn-Sham state to the localised orbitals.¹⁵ After evaluating E_U^0 , the corresponding Hubbard potential, *i.e.*, the added correction to the standard Kohn-Sham effective potential, is then obtained by taking the functional derivative of the corrective Hubbard energy with respect to the occupation matrix, yielding an orbital-dependent potential that acts only on the subspace defined by the chosen projector.¹⁴ The Hubbard correction therefore acts as an occupancy-based bias potential that corrects the total energy using the Hubbard *U* value and the occupation matrix, which necessitates careful choice of both the Hubbard *U* value and the projector. Choosing an appropriate Hubbard projector is particularly important for accurate simulations of materials with strong covalent character,^{15–18} and their specific representation prevents the transferability of Hubbard parameters across electronic structure codes that employ different types of Hubbard projector, *e.g.*, atomic orbitals,¹⁵ Wannier functions,^{19–21} projector augmented wave (PAW) projectors²² and muffin-tin orbitals (MTOs).¹⁶

Typically, the Hubbard *U* value is parameterised in DFT+*U* calculations with no consideration of the Hubbard projector, using semi-empirical benchmarking of DFT+*U*-predicted electronic, geometric and energetic properties against reference data from experiments or higher levels of theory.^{23,24} These semi-empirical approaches are reliant on accurate and available reference data, which prevents the high-throughput

optimisation of Hubbard *U* values for vast numbers of materials. Several first-principles approaches for computing Hubbard *U* values have also been developed, including the linear response approach based on constrained DFT (LR-cDFT),²⁵ density functional perturbation theory (DFPT),²⁶ constrained random phase approximation (cRPA)²⁷ and Hartree Fock based approaches (*e.g.*, UHF and ACBNO).^{28,29} Of these methods, LR-cDFT is most popular and has been applied in a planewave basis for the high-throughput optimisation of Hubbard *U* values for over 1000 transition metal oxides.³⁰ However, LR-cDFT can yield unphysical *U* values, suffers from numerical instability for closed-shell systems^{31,32} and is computationally expensive due to the requirement of calculations using large supercells.¹⁸ In addition, Hubbard *U* values computed using LR-cDFT are site-specific and therefore not transferable from stoichiometric systems with symmetry-equivalent sites to defective systems with broken symmetry.³³ The lack of transferability can prevent the simulation of experimentally observed electrical conductivities of defective TMOs, including the Li-ion battery cathode material $\text{LiCo}_{1-x}\text{Mg}_x\text{O}_2$, where deep defect states are predicted using Hubbard *U* values from LR-cDFT in a planewave basis, thus incorrectly suggesting material resistivity.⁵

To minimise the cost and instability of first-principles methods for computing Hubbard *U* values, active learning methods have been combined with global optimisation algorithms, such as Bayesian optimisation (BO) and Monte Carlo sampling, to minimise a cost function based on reproducing geometric and electronic properties predicted using higher levels of theory.^{34–36} In active learning, the cost function is refined by comparison with the output of successive DFT+*U* calculations, which means there is no *a priori* knowledge of the DFT+*U* potential energy surface and the entire approach must be repeated for different systems. Supervised machine and deep learning approaches have been used to improve the transferability of active learning methods for computing Hubbard *U* values, by attempting to learn the DFT+*U* potential energy surface for different materials. For example, BO and Random Forest Regression have been used to determine the structure-dependence of the Mn 3d Hubbard *U* value required to reproduce the electronic band structures of various MnO_x polymorphs computed using hybrid-DFT.³⁷ Similarly, equivariant neural networks have been used to estimate DFPT-predicted Hubbard *U* values using ground state atomic occupation matrices and interatomic distances for a range of materials, including Li_xFePO_4 and MnO_2 .³⁸ However, none of these methods address the parameterisation of Hubbard projectors, as well as differences in the numerical stability of DFT+*U* calculations with different Hubbard parameters.

The aforementioned challenges in DFT+*U* parameterisation (accuracy, numerical instability, computational cost and transferability across materials) are considered in this work in the context of simulations of stoichiometric and defective TMOs and REOs in a numerical atom-centred orbital (NAO) framework. In a NAO framework, there is a strong dependence of the accuracy and numerical stability of DFT+*U* calculations on both the Hubbard *U* value and the projector. Relying on semi-empirically derived Hubbard *U* values and the default atomic



Hubbard projector can result in inaccurate, unphysical (calculations terminate due to excessive polaron localisation) and unstable (SCF cycle does not converge) simulations of common TMOs, *e.g.*, TiO_2 and REOs, *e.g.*, CeO_2 . Thus, we demonstrate simultaneous optimisation of the Hubbard U value and the projector for Ti 3d orbitals in anatase TiO_2 using BO with a cost function defined using symbolic regression (SR), to minimise the errors of target properties relative to experimental references. BO is also subject to constraints on the DFT+ U -predicted covalency, to ensure the numerical stability of point defect calculations, as determined using support vector machines (SVMs). Combining SR, SVMs and BO in this manner avoids the need for multiple successive DFT+ U calculations, which significantly reduces the overall computational cost for Hubbard parameter optimisation compared to the existing first-principles and active learning approaches. We then extend the method across different materials by expanding the primary feature space for SR to include DFT-predicted orbital occupancies, basis set parameters and atomic material descriptors for a diverse training set of TMOs and REOs; application of hierarchical SR³⁹ allows us to optimise Hubbard U values and projectors from first-principles, by targeting orbital occupancies calculated using hybrid-DFT. The outcome is a transferable approach for the one-shot computation of Hubbard U values and projectors, with good accuracy that is also achieved for unseen materials. Overall, the work demonstrates the development of cost-effective and transferable machine learning-based workflows for more complete DFT+ U parameterisation, enabling more accurate and efficient simulations of complex energy materials.

2 Methodology

2.1 Electronic structure calculations

2.1.1 DFT. All electronic structure calculations were performed using the Fritz-Haber Institute *ab initio* materials simulation (FHI-aims) software,⁴⁰ which uses an all electron numerical atom-centred orbital (NAO) basis set, interfaced with the Python based Atomic Simulation Environment (ASE).⁴¹ The standard light basis set (2020) was used, with equivalent accuracy to the TZVP Gaussian-type orbital basis set,⁴² as decided after benchmarking of the TiO_2 formation energy (see SI, Section 1.1). Relativistic effects were accounted for using the zeroth order regular approximation (ZORA)⁴⁰ as a scalar correction, whilst the system charge and spin was set to zero. Periodic boundary conditions were applied using converged \mathbf{k} -point sampling (see SI Section S1.1), whilst the mBEEF meta-GGA exchange–correlation density functional was used,^{43,44} as defined in Libxc,⁴⁵ providing the best balance of accuracy and cost compared to other local and semi-local functionals (see SI Section S1.2). Hybrid-DFT reference calculations were performed using the PBE0 exchange–correlation density functional.^{46,47} Self-consistent field (SCF) optimisation of the electronic structure was achieved using a convergence criteria of 1×10^{-6} eV for the change in total energy, 1×10^{-4} eV for the change in the sum of eigenvalues and 1×10^{-6} e a_0^{-3} for the change in charge density. Geometry optimisation was

performed using the quasi-Newton BFGS algorithm^{48–51} with a force convergence criteria of 0.01 eV \AA^{-1} . Unit cell equilibrium volumes (V_0) were calculated by fitting to the Birch–Murnaghan equation of state using ASE.⁵² Where presented, formation energies (ΔE_{form}) for TiO_2 , CeO_2 and LiCoO_2 were calculated using the energies of bulk Ti (in the hexagonal close packed, HCP, crystal structure), bulk Ce, Li and Co (all in the cubic crystal structure) and an isolated O_2 molecule using:

$$\Delta E_{\text{form}} = E_{\text{compound}} - \sum_i n_i E_i - \frac{n_0}{2} E_{\text{O}_2} \quad (3)$$

where i denotes the metal species index in each compound and n_i (n_0) is the number of metal (oxygen) atoms in the formula unit.

2.1.2 DFT+ U parameterisation. All DFT+ U calculations were performed using the on-site definition of the occupation matrix and the Fully Localised Limit (FLL) double counting correction.¹⁵ In Section 3.1, a Hubbard correction is applied to correct for the Coulomb self-interaction of Ti 3d and Ce 4f orbital electrons in tetragonal TiO_2 and cubic CeO_2 , respectively, using the corresponding default Hubbard projector, which is the atomic NAO basis function in the minimal basis set (*i.e.*, the solution of the non spin-polarised single atom Schrödinger equation). The use of localised atomic basis functions provides a reasonable initial guess for constructing the correlated subspace for the DFT+ U correction, but is known to overestimate orbital occupation numbers leading to inaccurate predictions of oxidation states and energetic properties of complex oxides.^{53–55} Alternative definitions of the Hubbard projector can provide more accurate predictions of orbital occupancies, such as maximally-localised Wannier functions;⁵⁶ however, evaluating these projectors can introduce significant computational overhead. To maximise computational efficiency, FHI-aims allows the Hubbard projector (Φ_{Im}) to be defined as a linear combination of NAO basis functions (Φ_{Im}^i), specifically the atomic basis function in the minimal basis set and auxiliary hydrogenic basis functions for the same atomic site I and orbital magnetic quantum number m :

$$\Phi_{Im} = \sum_i c_i \phi_{Im}^i \quad (4)$$

where c_i denotes the linear expansion coefficients for a maximum of four basis functions per projector.⁵⁷

Where presented, modified atomic-like Hubbard projectors were therefore constructed as a linear combination of atomic and hydrogenic auxiliary basis functions, given the available basis functions in the light basis set (SI Section S1.3, Table S2). With this definition of the Hubbard projector, the use of basis sets with multiple radial functions for the same localised orbital can reportedly lead to erroneous ground state predictions due to the occupation of electronic states outside the correlated subspace;^{15,57} therefore, we restrict our study to the unmodified light basis set, which contains at most one auxiliary basis function per localised orbital as listed in the SI Section S1.3, Table S2. The Hubbard projector is therefore defined using the linear expansion coefficients c_1 and c_2 , which correspond to the atomic and auxiliary basis functions, respectively. Positive

values of c_2 were avoided to prevent the mixing of the metal d or f auxiliary basis functions with O 2p states in an unphysical manner, as determined by Kick *et al.* from comparisons with hybrid-DFT.¹⁵ Before constructing modified projectors, the auxiliary basis functions are subject to a Gram–Schmidt orthogonalisation with respect to the corresponding atomic functions, which avoids double counting of the Hubbard correction from the overlap of basis functions with long tails of radial decay.^{15,58}

2.1.3 Simulating defects and polarons. Constrained DFT+U calculations were performed using the “occupation matrix control” (OMC) method to fix polarons at specific atomic orbitals, by modifying the corresponding occupation matrices (which remain fixed for the entire calculation), *e.g.*, fixing the $3d_{z^2}$ orbital occupation number as 1 for a nearest neighbour Ti atom relative to an substitutional W dopant to simulate the formation of Ti^{3+} in W-doped TiO_2 (Fig. 1).^{15,59,60}

In Section 3.2, self-consistent DFT+U calculations are performed for TiO_2 using a modified atomic-like Ti 3d Hubbard projector, determined using the semi-empirical machine learning approach detailed in Section 2.2. This is expanded in Section 3.3, where self-consistent DFT+U calculations are performed for all materials in Table S2 in the SI Section S1.3, using modified atomic-like Hubbard projectors that were determined using the first-principles machine learning approach detailed in Section 2.3. Self-consistent defect calculations were performed using the “occupation matrix release” (OMR) method to initialise polaron(s); the DFT+U-predicted total energy (E) is then pre-converged using OMC until $\Delta E \leq 0.001$ eV, at which point the OMC constraint is relaxed and the orbital occupancies are calculated self-consistently.¹⁵ All point defect calculations in

this work were performed in a $3 \times 3 \times 3$ supercell, which avoids spurious long-range defect–defect interactions between periodic images. The oxygen vacancy formation energy (ΔE_{OV}) and the defect energies (ΔE_{defect}) following substitution of a host metal atom (Ti in TiO_2 and Co in $LiCoO_2$) with a Nb , W , Co , Mn , Pt , Au , Pd or Mg atom, are calculated as:

$$\Delta E_{OV} = E_{\text{oxygen deficient bulk}} + \mu_O - E_{\text{stoichiometric bulk}} \quad (5)$$

$$\Delta E_{\text{defect}} = E_{\text{doped bulk}} + \mu_{\text{host}} - E_{\text{stoichiometric bulk}} - \mu_{\text{dopant}} \quad (6)$$

where the chemical potentials were calculated using the energy of half an isolated O_2 molecule (μ_O), bulk Ti in the HCP crystal structure (μ_{Ti}) and the bulk dopant species (μ_{dopant}) in the cubic crystal structure except Mn (tetragonal) and Mg (HCP). No Hubbard correction was applied to the dopant atoms.

2.2 Semi-empirical machine learning approach

A semi-empirical approach was adopted to optimise the Ti 3d Hubbard U value and projector to enable accurate and numerically stable simulations of anatase TiO_2 using DFT+U-calculated properties of the TiO_2 unit cell (targets for regression) and the classified outcome of point defect calculations in a TiO_2 supercell using the OMR method (targets for classification), as illustrated in Fig. 2.

2.2.1 Symbolic regression. SR was performed using the Sure Independence Screening and Sparsifying Operator (SISSO) algorithm,⁶¹ as implemented in the SISSO++ package,^{62,63} to fit empirical correlations for target properties in terms of the primary features U , c_1 and c_2 . Empirical correlations were constructed by searching a non-linear secondary feature space by recursively combining the primary features using the algebraic

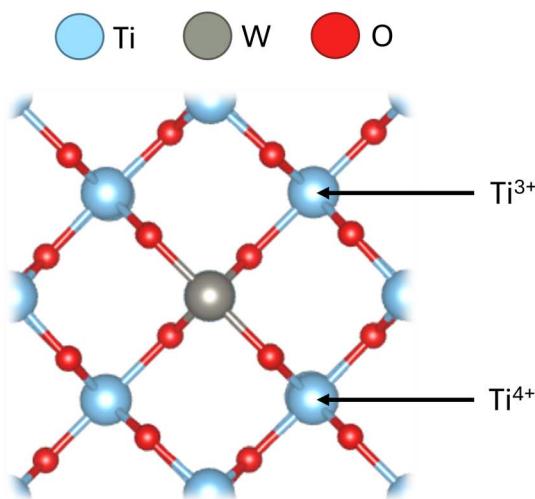


Fig. 1 Simulating an electron polaron in W-doped TiO_2 at a nearest neighbour Ti atom, denoted Ti^{3+} by setting the $3d_{z^2}$ orbital occupation number to 1. The electron polaron can be fixed using the occupation matrix control (OMC) method or initialised using the occupation matrix release (OMR) method. The diagonal elements of the occupation matrix correspond to orbital occupancies for a given magnetic quantum number ($3d_m$) in the order (from top left to bottom right) $3d_{-2}$, $3d_{-1}$, $3d_0$, $3d_1$ and $3d_2$ corresponding to the $3d_{xy}$, $3d_{yz}$, $3d_{z^2}$, $3d_{xz}$ and $3d_{x^2-y^2}$ orbitals, respectively.⁶⁰ Off-diagonals elements in the occupation matrix reflect orbital hybridisation. In this work, the diagonal elements of the occupation matrix are used as a quantitative measure of local chemical bonding environments and to construct workflows for Hubbard parameter optimisation by assessing how the occupation matrix varies with the chosen simulation method (*i.e.*, DFT, DFT+U or hybrid-DFT, detailed in the SI Section S1.3), Hubbard parameters and atomic properties of different materials.

Ti 3d Occupation Matrix

0.16098	0.00000	0.05529	0.00000	0.00000
0.00000	0.15932	0.00000	-0.06435	0.00000
0.05529	0.00000	1.00000	0.00000	0.00000
-0.00000	-0.06435	0.00000	0.15932	0.00000
0.00000	0.00000	0.00000	0.00000	0.09900
0.16098	0.00000	0.05529	0.00000	0.00000
0.00000	0.15932	0.00000	-0.06435	0.00000
0.05529	0.00000	0.10456	0.00000	0.00000
-0.00000	-0.06435	0.00000	0.15932	0.00000
0.00000	0.00000	0.00000	0.00000	0.09900



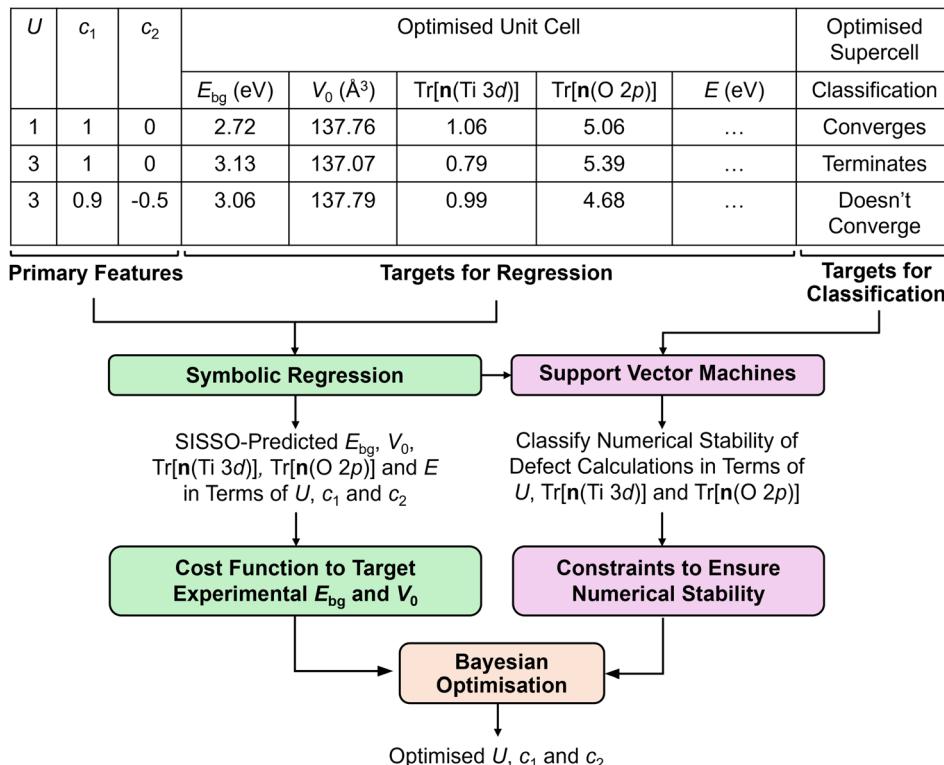


Fig. 2 Semi-empirical approach for simultaneously optimising the Ti 3d Hubbard U value and projector for anatase TiO_2 , using the DFT+ U -predicted band gap (E_{bg}), unit cell equilibrium volume (V_0), occupation matrix trace for Ti 3d ($\text{Tr}[\mathbf{n}(\text{Ti 3d})]$) and O 2p ($\text{Tr}[\mathbf{n}(\text{O 2p})]$) orbitals, total energy (E) and the classified results of bulk oxygen vacancy calculations using OMR.

operators $+$, $-$, \times , \div , x^2 , x^3 , \sqrt{x} , $\sqrt[3]{x}$, $\exp(x)$, $\log(x)$, $\sin(x)$, and $\frac{1}{x}$, before using sparse regression techniques to select a minimal set of secondary features and linear regression to optimise the coefficients of the final expression. Empirical correlations were fitted with up to three terms, using a recursive depth of three, yielding a linear combination of non-linear terms, *e.g.*, F_1 , F_2 and F_3 using the constants a_0 , a_1 , a_2 and a_3 for a three term correlation:

$$\text{Target} = a_0 + a_1 \times F_1 + a_1 \times F_2 + a_3 \times F_3 \quad (7)$$

Empirical correlations were constructed to estimate the DFT+ U -predicted band gap (E_{bg}), V_0 and traces of the Ti 3d ($\text{Tr}[\mathbf{n}(\text{Ti 3d})]$) and O 2p ($\text{Tr}[\mathbf{n}(\text{O 2p})]$) occupation matrices, with the accuracy of each correlation evaluated using the Pearson's coefficient of determination (R^2) and root mean squared error (RMSE). The SISSO correlations were then used to evaluate a unitless, regularised cost function (J^{SE}), which is defined as the Euclidean norm of two terms J_1^{SE} and J_2^{SE} . J_1^{SE} is itself the Euclidean norm of the percentage errors of the DFT+ U -predicted E_{bg} and V_0 of bulk anatase TiO_2 *versus* experimental references from the literature (E_{bg}^{Exp} and V_0^{Exp} , respectively).^{64,65} J_2^{SE} is an additional regularisation term to bias J^{SE} towards larger values of U and c_1 , which favours stronger polaron localisation at point defects that is consistent with the experimentally observed formation of mid-gap states within the TiO_2 band gap.^{15,66,67} J^{SE} therefore takes the form:

$$J^{\text{SE}} = \|J_1^{\text{SE}}, J_2^{\text{SE}}\| = \left\| \left\| \frac{100 \times (E_{bg}^{\text{DFT+}U} - E_{bg}^{\text{Exp}})}{E_{bg}^{\text{Exp}}} \right\|, \left\| \frac{100 \times (V_0^{\text{DFT+}U} - V_0^{\text{Exp}})}{V_0^{\text{Exp}}} \right\|, \left(\frac{1000}{\alpha U + c_1} \right) \right\| \quad (8)$$

where J_2^{SE} involves a constant $\alpha = 1 \text{ eV}^{-1}$ to ensure dimensional consistency, whilst being scaled by a factor of 1000 to ensure normalisation with respect to J_1^{SE} .

2.2.2 Support vector machines. To investigate numerical instability in self-consistent point defect calculations in TiO_2 , classification was performed with linear support vector machines (SVMs) using the Scikit-learn Python library.⁶⁸ The SVMs were used to determine the equations of the boundaries S_1 and S_2 separating regions in the feature space U , $\text{Tr}[\mathbf{n}(\text{Ti 3d})]$ and $\text{Tr}[\mathbf{n}(\text{O 2p})]$, where calculations rapidly terminated due to unphysical predictions or did not converge due to "charge sloshing" when simulating a bulk oxygen vacancy using the OMR method. SVM classification was also performed to investigate the relationship between the Hubbard parameters and erroneous oxygen vacancy formation energies, which ranged from -7.11 eV to 14.35 eV depending on the choice of U , c_1 and c_2 . Here, classification was performed to determine the equation of the linear boundary S_3 separating regions of "physical" ($4 \text{ eV} \leq \Delta E_{\text{ov}} \leq 6 \text{ eV}$) and "unphysical" ($\Delta E_{\text{ov}} < 4 \text{ eV}$ or $\Delta E_{\text{ov}} > 6 \text{ eV}$) oxygen vacancy formation energies, in terms of the partial derivatives of the SISSO-predicted total energy (E^{SISSO}) with



respect to U , c_1 and c_2 . Numerical partial derivatives of E^{SISSO} with respect to each Hubbard parameter $U\left(\frac{\partial E^{\text{SISSO}}}{\partial U}\right)$, $c_1\left(\frac{\partial E^{\text{SISSO}}}{\partial c_1}\right)$ and $c_2\left(\frac{\partial E^{\text{SISSO}}}{\partial c_2}\right)$ were calculated using the forward finite difference method with a step size of 0.01. Both SR and SVM classification were performed using a training set of ≤ 60 geometry optimised unit cells and bulk oxygen vacancy calculations, where all computational settings are kept constant except the Ti 3d Hubbard parameters. Feature scaling was performed for all primary features and target properties (denoted using \bar{x}) for the SISSO correlation for V_0 and SVM boundaries S_1 and S_2 . The normalisation constants are listed with the non-linear terms, constants and accuracy metrics for all SISSO correlations and SVM boundaries in the SI Section S2.1.

2.2.3 Bayesian optimisation. BO was performed using the GPyOpt Python library⁶⁹ to probabilistically search the Hubbard parameter space by minimising J^{SE} whilst satisfying three constraints, including those derived from S_1 and S_2 . The Hubbard parameter space was searched using the standard Expected Improvement acquisition function,⁷⁰ with a sampling weight of 0.01 to encourage parameter exploration within bounds for U between 0.5 eV and 5 eV, c_1 between 0 and 1.3 and c_2 between -0.6 and 0; beyond these values, numerical instability including calculation termination and non-convergence was observed when simulating the TiO_2 unit cell. An initial population of 1000 combinations of Hubbard parameters were defined using Latin Hypercube Sampling,⁷¹ using the pyDOE Python library,⁷² to build a surrogate model of J^{SE} that was minimised further using BO for 350 iterations. Sampled Hubbard parameters that violated constraints were penalised by assigning them a high value of $J^{\text{SE}} = 1000$, therefore discouraging the exploration of the Hubbard parameter space that leads to numerically unstable calculations. The effectiveness of BO in identifying the global minimum J^{SE} was assessed by comparing the BO-sampled landscape of J^{SE} with that evaluated using random sampling for 50 000 iterations.

2.3 First-principles machine learning approach

To extend the semi-empirical approach across different materials, a first-principles approach was adopted to parameterise Hubbard U values and projectors by targeting the O 2p orbital occupancies calculated using hybrid-DFT, which was identified as crucial to enable self-consistency of DFT+ U simulations of intrinsic and extrinsic defects in TiO_2 using the OMR method. The first-principles approach was similar to the semi-empirical approach outlined in Section 2.2, by aiming to ensure the accuracy and numerical stability of DFT+ U simulations of stoichiometric and defective TMOs and REOs using generalised symbolic regression and classification, as illustrated in Fig. 3.

2.3.1 Hierarchical symbolic regression. To generalise SR across different materials, the primary feature space was expanded beyond the Hubbard parameters U , c_1 and c_2 , to include data that can either be determined from a single reference DFT calculation or is widely available in the literature.

The expanded primary feature space included (1) basis set parameters for the correlated subshell subject to the Hubbard correction, such as the type (Z_{type} , *i.e.*, hydrogenic or ionic) and effective core charge (Z_{val}) of the auxiliary basis function, (2) DFT-predicted metal d or f and O 2p orbital occupancies averaged over all atoms in the unit cell and (3) atomic material descriptors, including the metal atom electronegativity (χ) and atomic radius (r), as well as the outer subshell type (S , encoding d or f subshells), principal quantum number (Q) and number of electrons in the ion (e^{ion}). Both Z_{type} and S were label-encoded as integers to enable their use in SR.

The expanded set of 20 primary features makes the SISSO method computationally intractable due to the attempted exhaustive search of the secondary feature space, which scales exponentially with the number of primary features, therefore, a two-step hierarchical SISSO (HI-SISSO)³⁹ approach was adopted where the output from a first step using SISSO, with 13/20 of all primary features (Hubbard parameters and DFT-predicted orbital occupancies), was used as an input for a second step using HI-SISSO where the remaining primary features are included as inputs. HI-SISSO was used to fit ten empirical correlations to estimate DFT+ U -predicted orbital occupancies across the full range of magnetic quantum numbers (m), with seven correlations for $m = -3$ to +3 (grouping together d and f orbitals) and three correlations for $m = -1$ to 1 for O 2p orbitals. The training set contained 197 sets of DFT+ U -calculated orbital occupancies from optimised unit cells of anatase and rutile TiO_2 (46%), CeO_2 (13%), Cu_2O (11%), Y_2O_3 (11%), ZrO_2 (11%), WO_3 (7%) and MoO_3 (1%), where the percentages correspond to the proportion of each material in the dataset. LiCoO_2 and LiFePO_4 were used as blind test cases with no training data. The constants, accuracy metrics and non-linear terms F_1 , F_2 and F_3 for all HI-SISSO correlations are listed in the SI Section S2.2.1. As illustrated by the parity plots in Fig. 4 for O 2p orbitals, the HI-SISSO approach (including basis set parameters and atomic descriptors) improved the predictive accuracy of all three correlations compared to the single step SISSO approach, which is equivalent to Δ -machine learning with respect to DFT-predicted orbital occupancies.⁷³

The HI-SISSO-predicted O 2p occupancies were then used to construct a cost function for optimising Hubbard U values and projectors from first-principles, J^{FP} , by targeting O 2p orbital occupancies calculated using hybrid-DFT, as outlined in Section 3.3.1.

$$J^{\text{FP}} = \left\| \frac{100 \times (n_m^{\text{O2p DFT+}U} - n_m^{\text{O2p PBE0}})}{n_m^{\text{O2p PBE0}}} \right\|, \quad n_m = (n_{-1}, n_0, n_1) \quad (9)$$

2.3.2 Symbolic classification. The observed numerical instability of self-consistent DFT+ U simulations of point defects in TiO_2 , including excessive polaron localisation that causes calculations to terminate and charge sloshing preventing SCF convergence, was observed when modelling point defects across the broader range of TMOs and REOs in Table S2 in the SI Section S1.3. Therefore, the use of SVMs for classifying the stability of point defect calculations in Section 2.2.2 was



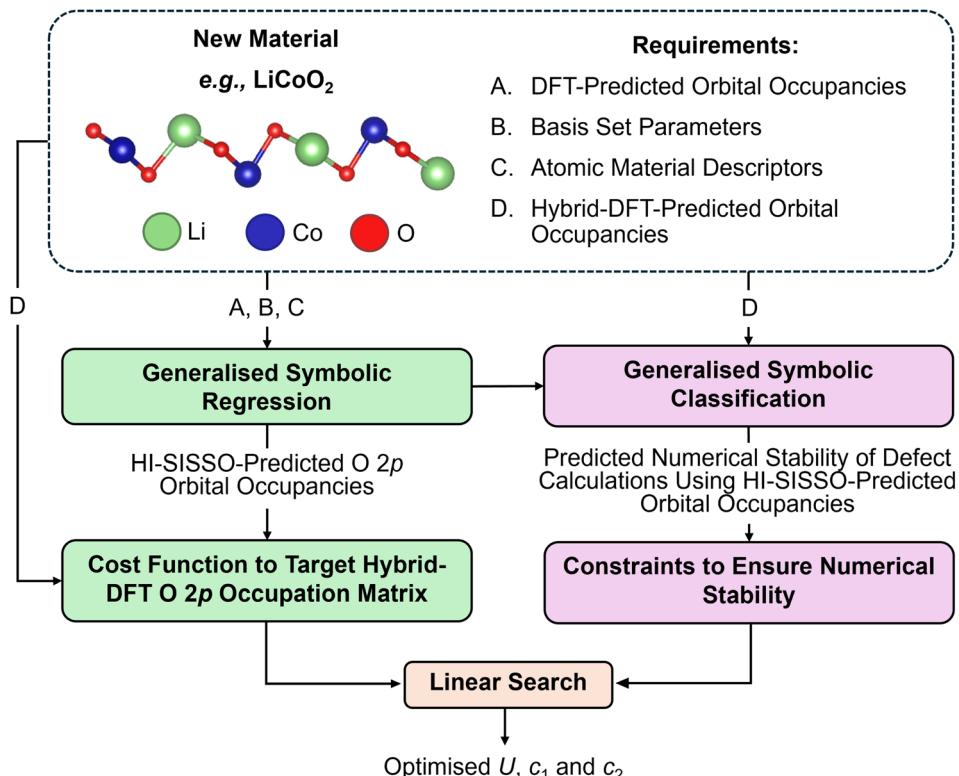


Fig. 3 First-principles approach for optimising the Hubbard U value and the projector. Generalised symbolic regression is used to target the hybrid-DFT-predicted O 2p occupation matrix. Generalised symbolic classification is used to determine constraints on the Hubbard parameter space to ensure numerically stable point defect calculations.

generalised across materials. Generalised classification was achieved by defining new primary features to account for the different degrees of covalent character across the materials in Table S2 in the SI Section S1.3, which is key for the generalisation of predictive models across complex oxides.⁷⁴ The primary features for generalised classification were U , J^{FP} , the average error in the DFT+ U -predicted metal d or f orbital occupancies relative to hybrid-DFT (E^{metal}) and the ratio of the

traces of the metal d or f and O 2p occupation matrices predicted using hybrid-DFT (R^{hybrid}), as outlined in Section 3.3.2.

$$E^{\text{metal}} = \left\| \frac{100 \times (n_m^{\text{metal d or f DFT+U}} - n_m^{\text{metal d or f PBE0}})}{n_m^{\text{metal d or f PBE0}}} \right\|, \quad (10)$$

$$n_m = (n_{-3}, n_{-2}, n_{-1}, n_0, n_1, n_2, n_3)$$

$$R^{\text{hybrid}} = \frac{\text{Tr}[\mathbf{n}(\text{metal d or f})]^{\text{PBE0}}}{\text{Tr}[\mathbf{n}(\text{O 2p})]^{\text{PBE0}}} \quad (11)$$

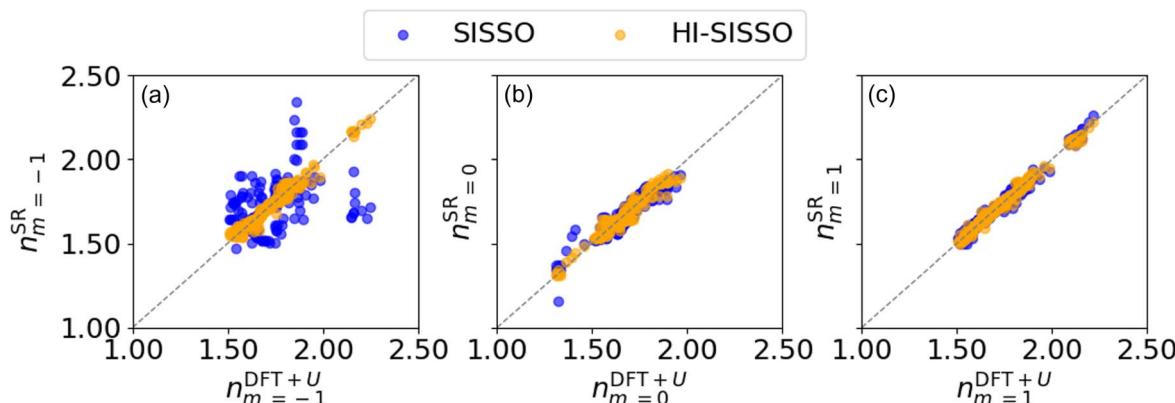


Fig. 4 Parity plots for the DFT+ U - and SR-predicted O 2p orbital occupancies for (a) $n_m = -1$, (b) $n_m = 0$ and (c) $n_m = 1$. Blue markers show the predictions using a single step SISSO fitting using the primary features U , c_1 , c_2 and all DFT predicted metal d or f and O 2p orbital occupancies. Orange markers show the predictions after a second HI-SISSO fitting, where the outputs from the first step are included within a new set of primary features including S , Z_{type} , Z_{val} , Q , χ , e^{ion} and r .



Generalised constraints on the Hubbard parameter space were determined using two linear SVMs to determine the equations of the boundaries S_4 and S_5 that separated regions in the primary feature space leading to the termination and non-convergence of bulk oxygen vacancy calculations using the OMR method. The training set consisted of 86 DFT+ U simulations across anatase and rutile TiO_2 (76%), CeO_2 (6%), ZrO_2 (6%), MoO_3 (6%), WO_3 (5%) and Cu_2O (2%), where the percentages correspond to the proportion of each material in the dataset. To reduce the number of misclassified data points associated with S_4 and S_5 , classification was performed symbolically using the SISSO algorithm to recursively combine the primary features using the same algebraic operators as in SR, but with the objective of minimising the number of data points in the overlap region of a two-dimensional convex hull.⁶³ The secondary features generated from SISSO were then used as inputs for two linear SVMs, which identified simple boundaries to perform binary classifications in a highly non-linear feature space. The associated constants and accuracy metrics for S_4 and S_5 are listed in the SI Section S2.2.1.

2.3.3 One-shot optimisation of Hubbard parameters. Optimisation of U , c_1 and c_2 from first-principles was performed by a linear search of the landscape of the HI-SISSO-predicted cost function ($J_{\text{predicted}}^{\text{FP}}$) for each material, over the range of U between 0 eV and 5 eV, c_1 between 0.5 and 1 and c_2 between -0.6 and 0, with each feature split into 50 intervals. The output of each linear search was a family of candidate solutions for a material, with several combinations of U , c_1 and c_2 optimised to minimise $J_{\text{predicted}}^{\text{FP}}$ (see SI Section S2.2.2). The accuracy of the HI-SISSO correlations to predict O 2p orbital occupancies was evaluated by comparing $J_{\text{predicted}}^{\text{FP}}$ to the corresponding DFT+ U -computed cost function ($J_{\text{validated}}^{\text{FP}}$) for up to ten different combinations of Hubbard U values and projectors per material (94 in total), before calculating the mean absolute error (MAE), which is averaged across all tested Hubbard parameters (N) for each material:

$$\text{MAE} = \frac{1}{N} \sum_{i=1}^N \left| J_{\text{predicted},i}^{\text{FP}} - J_{\text{validated},i}^{\text{FP}} \right| \quad (12)$$

The relationship between the accuracy of the one-shot approach for minimising $J_{\text{predicted}}^{\text{FP}}$ and the training set size for each material was investigated using the Mahalanobis distance (D_M)⁷⁵ to quantify the distance of the primary feature vector for each material (\mathbf{x}), in a reduced two dimensional feature space determined using principal component analysis (PCA) with the Scikit-learn Python library,⁶⁸ from the mean vector of the training data ($\boldsymbol{\kappa}$), using the inverse covariance matrix of the training data (\mathbf{C}^{-1}):

$$D_M = \sqrt{(\mathbf{x} - \boldsymbol{\kappa})^T \mathbf{C}^{-1} (\mathbf{x} - \boldsymbol{\kappa})} \quad (13)$$

An integrated one-shot approach for optimising Hubbard U values and projectors from first-principles was tested for computing the Co 3d Hubbard U value and projector for the simulation of stoichiometric, Mg-doped and oxygen defective

LiCoO_2 (*i.e.*, $\text{LiCo}_{1-x}\text{Mg}_x\text{O}_{2-x}$), which is unseen by any of the trained regression or classification models. Here, the three HI-SISSO correlations to estimate the DFT+ U -predicted O 2p orbital occupancies (for $m = -1$, 0 and 1) were used to screen the landscape of $J_{\text{predicted}}^{\text{FP}}$ for stoichiometric LiCoO_2 , before all Hubbard parameters that violate the generalised constraints S_4 and S_5 , which are evaluated using all ten HI-SISSO correlations, are removed from the landscape. The remaining Hubbard parameters were reduced to a smaller set of candidates with K-means clustering, using the Scikit-learn Python library,⁶⁸ which uses unsupervised learning to partition the landscape of $J_{\text{predicted}}^{\text{FP}}$ into smaller clusters by minimising intra-cluster variance. The centroids of these clusters were then used as screened Hubbard parameters for the simulation of stoichiometric and defective LiCoO_2 , using the OMR method.

3 Results and discussion

3.1 Projector sensitivities in DFT+ U simulations

3.1.1 Stoichiometric oxides. DFT+ U is known to be non-trivial when simulating the ground state character (*i.e.*, metallic, semiconducting or insulating) of TMOs and REOs. For example, in a planewave basis, material-dependent transitions in the DFT+ U -predicted ground state from metallic to insulating can occur upon increasing the Hubbard U value, which can restore the experimentally observed electronic structures of Mott insulators such as NiO and Ce_2O_3 (ref. 76–79) and point defects in CeO_2 surfaces.⁷⁸ Furthermore, erroneous changes in the DFT+ U -predicted hybridisation between metal d and O 2p orbitals can drive the predictions of ground state crystal structures and magnetic properties away from experimental observations, as is reported for BaTiO_3 and layered AMoO_2 ($\text{A} = \text{Li}$, Na , K).^{80,81} The existence of metastable states on the DFT+ U potential energy surface, near integer orbital occupations, can also result in erroneous trapping in local energy minima using local optimisation algorithms, resulting in incorrect ground state predictions for point defects in actinide oxides such as UO_2 .⁵⁹

In a NAO framework, similar observations are made when modelling stoichiometric REOs using the default atomic Hubbard projector. For example, applying a Hubbard correction to Ce 4f electrons in stoichiometric CeO_2 , using the atomic Ce 4f Hubbard projector, results in an insulator-metal transition (IMT) in the predicted ground state. Upon increasing the Ce 4f Hubbard U value, there is a monotonic change in the DFT+ U -predicted E_{bg} in Fig. 5(a) and ΔE_{form} in Fig. 5(b) between U values of 0 eV to 9 eV. Beyond $U = 9$ eV, which would be required if adopting the standard approach of benchmarking against the experimental E_{bg} of 3.2 eV,⁸² there is a sudden deviation in these trends and DFT+ U predicts strong electron localisation in the Ce 4f $m = -2$ orbital, corresponding to metallic behaviour with no band gap. To trace the root cause of the observed IMT at $U = 9.5$ eV, constrained DFT+ U calculations were performed using the ground state Ce 4f occupation matrix calculated using $U = 9.5$ eV, but with the $m = -2$ and $m = -3$ orbital occupancies systematically varied and all other occupancies fixed. As illustrated in Fig. 5(c), there is a metallic global energy minimum

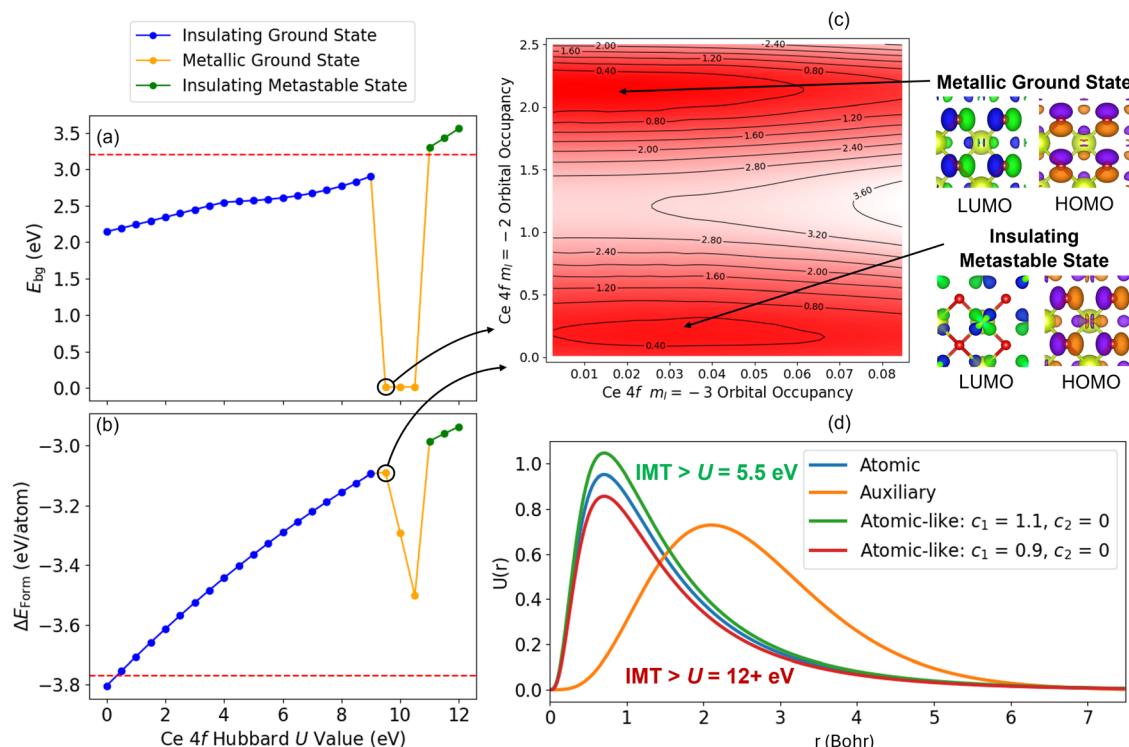


Fig. 5 Overview of errors when modelling stoichiometric CeO_2 using the default Ce 4f atomic Hubbard projector, including the variation in the DFT+ U -predicted (a) band gap and (b) formation energy with respect to the Ce 4f Hubbard U value, relative to experimental references denoted by the red dashed lines.^{82,83} Blue markers correspond to insulating ground states, yellow markers correspond to metallic ground states and green markers correspond to insulating metastable states. (c) Contour plot of the constrained DFT+ U -predicted total energy relative to the ground state energy at $U = 9.5$ eV, after constraining the $m = -2$ and $m = -3$ orbital occupancies. The two regions in dark red correspond to global and low-lying local minima in the potential energy surface with respect to Ce 4f orbital occupancies. The metallic global minimum is 0.273 eV more stable than the insulating local minimum. (d) The radial functions corresponding to the atomic Ce 4f (blue) and hydrogenic auxiliary (orange) basis functions available for constructing a modified atomic-like Hubbard projector. The green and red radial functions correspond to modified projectors that do not include any contribution from the hydrogenic auxiliary function (i.e., $c_2 = 0$) and are noted with the corresponding shift of the observed IMT.

and an insulating low-lying metastable state in the potential energy surface, therefore the observed IMT is caused by the small energy differences between these energy minima, which decreases as the Hubbard U value increases. For $U = 9.5$ eV, self-consistent determination of the Ce 4f occupation matrix leads to a metallic solution, irrespective of the initial occupation matrix; therefore, we conclude that there are no other insulating solutions with lower energy than the metallic solution and that this represents an IMT in the potential energy surface.

Beyond $U = 11$ eV, the insulating ground state character is seemingly restored in Fig. 5(a) and (b); however, these were found to be metastable states as confirmed using OMR with a modified initial Ce 4f occupation matrix, which enabled convergence to the true metallic ground state that exists at all U values beyond the IMT at $U = 9.5$ eV. The IMT was also found to vary with the definition of the Hubbard projector, as shown in Fig. 5(d), where the more localised projector in green brings the IMT forward to $U > 5.5$ eV and the more diffuse projector defers the IMT beyond $U = 12$ eV. The results exemplify the importance of developing new strategies for parameterising the Hubbard U value and projector to enable the accurate simulation of insulating ground states of REOs like CeO_2 , whilst

avoiding erroneous IMTs and metastable states; this goal cannot be achieved using the standard approach of semi-empirical benchmarking of the Hubbard U value to reproduce the experimental E_{bg} .

3.1.2 Defective oxides. Whilst DFT+ U simulations using semi-empirically-derived Hubbard U values and the default atomic Hubbard projector can accurately model point defects in TMOs such as $\text{Li}_4\text{Ti}_5\text{O}_{12}$,^{84,85} the numerical stability of point defect calculations is generally highly sensitive to the choice of the Hubbard U value, as illustrated in Fig. 6 for anatase TiO_2 . Upon increasing the Ti 3d Hubbard U value, there is a monotonic change in the DFT+ U -predicted E_{bg} in Fig. 6(a) and ΔE_{form} in Fig. 6(b) of anatase TiO_2 . An appropriate Hubbard U value could be chosen by considering the compromise in accuracy of these properties *versus* the experimental references denoted by the red dashed lines in each plot; however, the numerical stability of DFT+ U simulations of a bulk oxygen vacancy in anatase TiO_2 were found to vary strongly with both the Hubbard U value and projector. For example, Fig. 6(c) shows the radial functions of two modified atomic-like Ti 3d Hubbard projectors (green and red functions), which are examples of a series of systematically tested Hubbard projectors for the simulation of

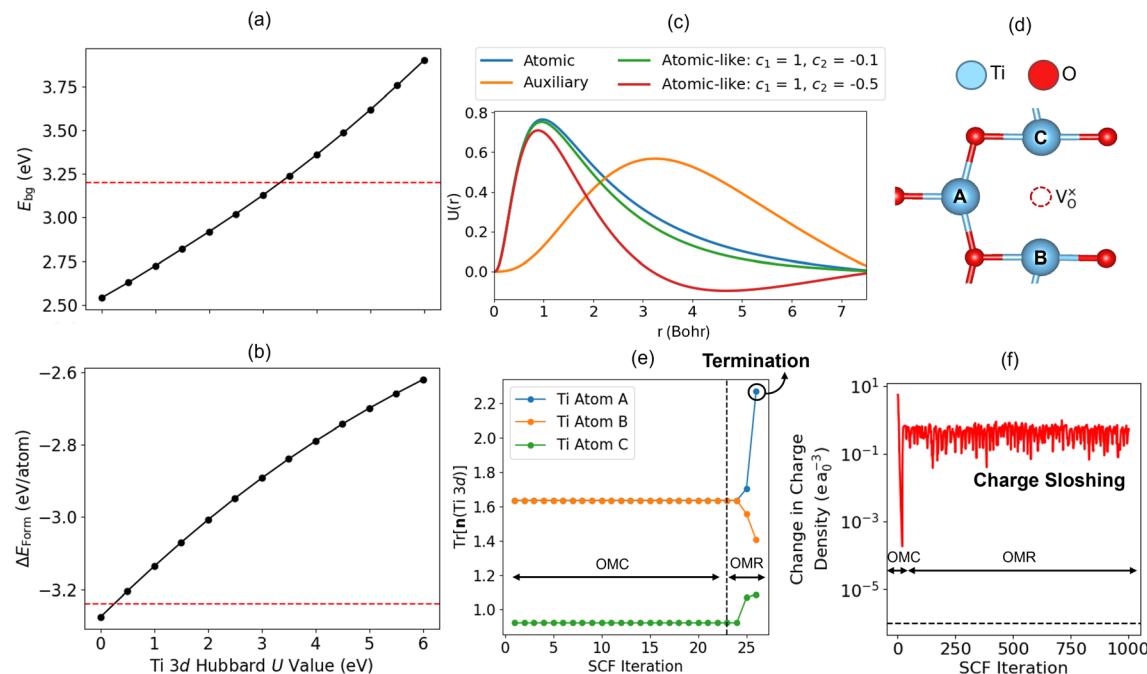


Fig. 6 Overview of errors when modelling stoichiometric and defective TiO_2 , including the variation of the DFT+ U -predicted (a) band gap and (b) formation energy with respect to the Ti 3d Hubbard U value, using the default atomic Ti 3d Hubbard projector, relative to experimental references denoted by the red dashed lines.^{64,87} (c) The radial functions corresponding to the atomic Ti 3d (blue) and hydrogenic auxiliary (orange) basis functions available for constructing a modified atomic-like Hubbard projector. The green and red radial functions correspond to modified projectors that incorporate a contribution from hydrogenic auxiliary function given by the linear expansion coefficient c_2 . (d) The nearest neighbour Ti atoms surrounding a bulk oxygen vacancy in anatase TiO_2 . (e) The evolution of $\text{Tr}[n(\text{Ti 3d})]$ for Ti atoms A, B and C in (d) during an oxygen vacancy calculation using $U = 3$ eV, $c_1 = 1$, $c_2 = -0.1$, which leads to calculation termination due to excessive polaron localisation at atom A, after 3 SCF iterations of OMR (which begins after 23 SCF iterations of OMC). (f) The evolution of the change in charge density during SCF optimisation, during the 1st geometry optimisation step for an oxygen vacancy calculation using $U = 3$ eV, $c_1 = 1$, $c_2 = -0.5$. The calculation does not achieve the convergence criteria of changes in charge density below $1 \times 10^{-6} \text{ e a}_0^{-3}$, denoted by the black dashed line, due to charge sloshing.

a bulk oxygen vacancy using the OMR method. In each simulation, two Ti^{3+} polarons were initialised at Ti atoms A and B in Fig. 6(d), which are nearest neighbours relative to the oxygen vacancy. With some combinations of Hubbard U values and projectors, full geometry optimisation successfully completed, whilst in other cases, the simulations were terminated within 2 to 5 iterations of self-consistent optimisation of the system occupation matrices, due to excessive polaron localisation at Ti atom A resulting in the predicted $3d_{z^2}$ orbital occupancy increasing beyond 4 (which is the condition for termination) in Fig. 6(e). With other combinations of Hubbard U values and projectors, the OMR calculations did not converge due to strong oscillations in the charge density (Fig. 6(f)), which is known as charge sloshing between partially filled, degenerate orbitals and is often associated with metallic systems.⁸⁶

3.1.3 Tracing numerical instability to the Hubbard projector. The termination of defect calculations in Fig. 6(e) was observed for Hubbard U values > 1 eV using the default atomic Ti 3d Hubbard projector and occurred irrespective of initialising Ti^{3+} polarons further away from the oxygen vacancy as well as tuning available parameters such as SCF mixing parameters and initial occupation matrices. We also tested initialising Ti^{3+} polarons in different Ti 3d orbitals (other than the $3d_{z^2}$ orbital)

and performing local symmetry breaking *via* targeted bond distortions; however, these did not alleviate the termination of defect calculations in a NAO framework, despite their reported success for aiding SCF convergence in planewave codes.^{60,88,89} The SCF non-convergence due to charge sloshing in Fig. 6(f) was also very difficult to alleviate with common strategies. After extensive testing, we could find no robust strategy to mitigate this sloshing, despite tuning available parameters including the basis set size, initial geometries and occupation numbers, SCF mixing parameters, Gaussian broadening parameters, Kerker preconditioning,⁹⁰ the OMR pre-convergence criteria, \mathbf{k} -point spacing and using wavefunction restarts. Whilst the charge sloshing in Fig. 6(f) appears insensitive to the aforementioned strategies to improve SCF convergence, other cases of SCF non-convergence such as plateauing of the electron density are more straightforward to address, as observed for Mn-doped rutile TiO_2 in Section 3.2.4, which requires an increased Pulay mixing history beyond the default value. The issue of charge sloshing therefore appears to be specific to DFT+ U in the NAO framework, although planewave implementations are not without their own projector-related issues, as highlighted by Warda *et al.*, who discuss the challenge of spurious Hubbard forces and the resulting inaccuracies in the predicted phase stabilities



of AUO_4 ($\text{A} = \text{Ni, Mg, Co, Mn}$) compounds when using atomic Hubbard projectors.⁹¹

We note three approaches that are observed to overcome the numerical instabilities when simulating point defects using DFT+ U in a NAO framework. Kick *et al.* overcame SCF non-convergence when simulating Ti^{3+} polarons at oxygen vacancies in a rutile (110) TiO_2 surface by increasing the effective core charge (Z_{val}) of the Tier 1 hydrogenic auxiliary basis function from $2.7e$ to $4.4e$, before using an atomic Ti 3d Hubbard projector to define the basis for the Hubbard correction.¹⁵ Using very small Hubbard U values, or employing constrained DFT+ U using the OMC method, can also overcome the observed numerical instability; however, we have previously shown that this comes at the expense of accuracy when modelling polarons in Nb- and W-doped bulk anatase and rutile TiO_2 .⁶⁷ For these systems, self-consistent resolution of the system occupation matrices was achieved using a modified Ti 3d Hubbard projector, defined as a linear combination of the atomic and Tier 1 hydrogenic basis functions with the expansion coefficients $c_1 = 0.828$ and $c_2 = -0.561$ determined by Jakob and Oberhofer using a first-principles generalised LR-cDFT method in FHI-aims.⁵⁷ With a modified Ti 3d Hubbard projector, DFT+ U successfully simulated the polymorph-dependent formation of Nb^{4+} and W^{5+} polarons as observed in electron paramagnetic resonance (EPR) spectroscopy, which cannot be rationalised by the current planewave DFT+ U studies in the literature.⁶⁷ It is therefore essential to understand how to define an appropriate Hubbard projector to enable DFT+ U simulations with appreciable Hubbard U values without sacrificing self-consistency and remaining robust with respect to the default basis sets, and we investigate this challenge herein for TiO_2 before establishing a generalised understanding for a broader range of TMOs and REOs.

3.2 Bayesian optimisation of the Ti 3d Hubbard projector

3.2.1 Method configuration. The semi-empirical cost function (J^{SE}) defined in Section 2.2.1 favours regions in the Hubbard parameter space that achieve a compromise between modelling localised polarons at point defects and the accurate geometric and electronic structure of stoichiometric anatase TiO_2 . To rapidly sample the Hubbard parameter space without requiring multiple DFT+ U calculations, the terms in J^{SE} were evaluated using SISSO-computed empirical correlations for the DFT+ U -predicted E_{bg} , \bar{V}_0 , $\text{Tr}[\mathbf{n}(\text{Ti 3d})]$ and $\text{Tr}[\mathbf{n}(\text{O 2p})]$ in terms of the primary features U , c_1 and c_2 , as listed in the SI Section S2.1. Three constraints for sampling the Hubbard parameter space were also defined to ensure physicality of the model and avoid numerical instability during point defect calculations using OMR, which result in either termination or non-convergence in Fig. 6. Hubbard parameters that are predicted by the SISSO models to give a negative occupation matrix trace for Ti 3d or O 2p orbitals, or occupation matrix traces that deviate from the respective hybrid-DFT-predicted occupation matrix trace by over 50%, were excluded. The third constraint was applied using two linear SVMs that classify the validity of a bulk oxygen vacancy calculation in terms of the normalised \bar{U} ,

$\overline{\text{Tr}}[\mathbf{n}(\text{Ti 3d})]$ and $\overline{\text{Tr}}[\mathbf{n}(\text{O 2p})]$, as illustrated in Fig. 7, which shows the boundaries S_1 and S_2 that separate regions in the Hubbard parameter space that lead to unphysical (termination), charge sloshing (preventing SCF convergence) and ground state (stable convergence) calculation outcomes.

Fig. 7 illustrates how the numerical stability of defect calculations in TiO_2 is sensitive to the DFT+ U -predicted covalency, with calculation termination occurring at high covalency, *i.e.*, $\overline{\text{Tr}}[\mathbf{n}(\text{O 2p})] \gg \overline{\text{Tr}}[\mathbf{n}(\text{Ti 3d})]$ and charge sloshing occurring at high metallicity, *i.e.*, $\overline{\text{Tr}}[\mathbf{n}(\text{Ti 3d})] \gg \overline{\text{Tr}}[\mathbf{n}(\text{O 2p})]$. To ensure the successful convergence of point defect calculations whilst mitigating the effects of the changing DFT+ U -predicted covalency, the equations of the decision boundaries S_1 and S_2 (trained on DFT+ U data, with all constants listed in the SI Section S2.1) were used as constraints on the sampled Hubbard parameter space, based on the SISSO-computed cost function J^{SE} , with the critical values for S_1 and S_2 chosen based on the convex hull plots in Fig. 7:

$$S_1 > -9.84 \wedge S_2 > -9.16 \quad (14)$$

3.2.2 Bayesian optimisation and defect energy corrections.

BO was used to search the Hubbard parameter space by minimising J^{SE} whilst satisfying the constraints on the SISSO-predicted traces of the Ti 3d and O 2p occupation matrices, $\text{Tr}[\mathbf{n}(\text{Ti 3d})]^{\text{SISSO}}$ and $\text{Tr}[\mathbf{n}(\text{O 2p})]^{\text{SISSO}}$, respectively and the SVM-derived constraints S_1 and S_2 , as illustrated in Fig. 8.

Fig. 8(a) and (b) show the results of BO and random sampling, respectively, where BO is able to efficiently optimise U , c_1 and c_2 , yielding an almost equivalent set of optimised Hubbard parameters, to those obtained using random sampling, with minimal values of J^{SE} . This is further supported by Fig. 8(c), which shows the values of J^{SE} corresponding to the sampled Hubbard parameters. The markers in pink show the first 1350 randomly sampled Hubbard parameters, where constraint violations do not inform subsequent sampling, making the approach highly inefficient. The markers in purple correspond to BO, where the 1000 randomly sampled points selected using Latin Hypercube Sampling are used to train the BO prior and enable efficient optimisation of U , c_1 and c_2 . The Hubbard parameters $U = 2.749$ eV, $c_1 = 0.758$ and $c_2 = -0.354$, from the region of lowest J^{SE} in Fig. 8(a) and (b), were tested for the simulation of both anatase and rutile TiO_2 polymorphs. With the refined atomic-like Ti 3d Hubbard projector, oxygen vacancies and the substitutional dopants Nb, W, Co, Mn, Pt, Au and Pd all successfully converged to the ground state, whilst 11 of these 16 calculations failed when using the same Hubbard U value with the default atomic Ti 3d Hubbard projector (listed in Section 3.2.3, Table 2).

Refining the Ti 3d Hubbard projector therefore enables numerically stable self-consistent defect calculations; however, the predictions for anatase TiO_2 have unphysical defect energies, ranging from -11.59 eV and -1.28 eV; the same is not observed for defective rutile TiO_2 , with defect energies ranging from -0.97 eV to 8.22 eV. These unphysical defect energies for anatase TiO_2 necessitate further study into how tuning the Ti 3d



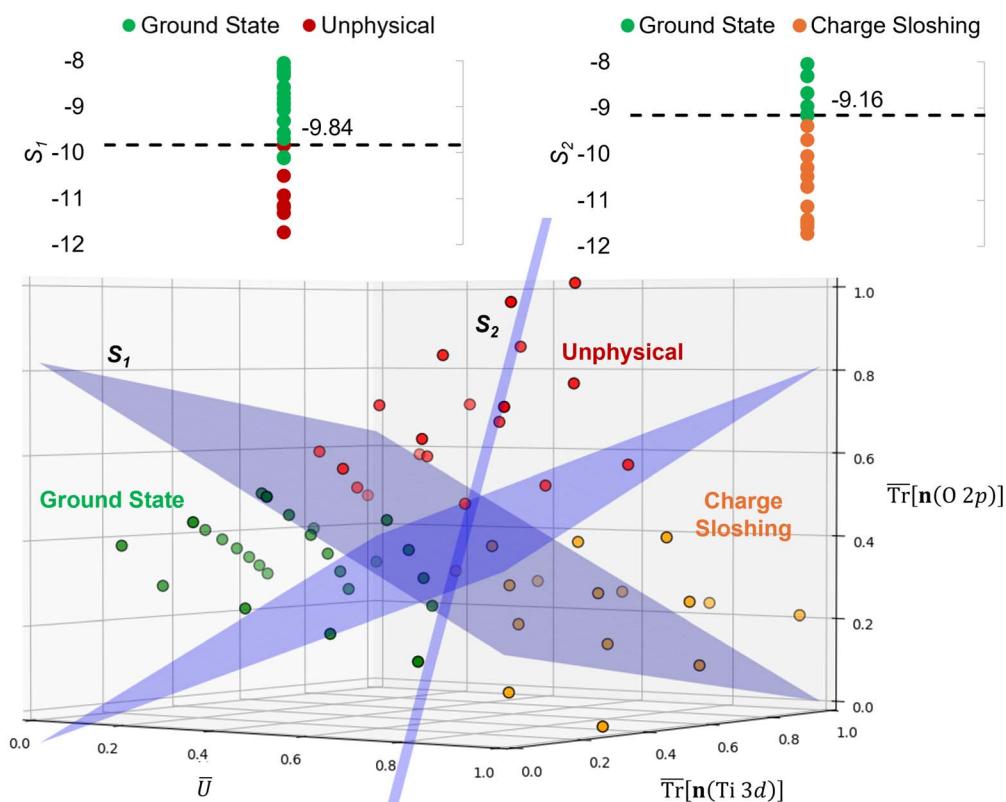


Fig. 7 Illustration of the linear boundaries used to classify simulations of a bulk oxygen vacancy in anatase TiO_2 . The boundaries separate successful convergence (green markers), termination due to an unphysical ground state (red markers) and charge sloshing preventing SCF convergence (orange markers). The convex hull associated with each binary classification S_1 and S_2 is shown to illustrate the basis for constructing the constraint in eqn (14).

Hubbard projector affects the DFT+ U -predicted total energy (E). As discussed in the SI Section S2.1.2, we construct an additional SVM constraint S_3 to classify whether a particular combination of U , c_1 , and c_2 leads to “physical” ($4 \text{ eV} \leq \Delta E_{\text{ov}} \leq 6 \text{ eV}$) or “unphysical” ($\Delta E_{\text{ov}} < 4 \text{ eV}$ or $\Delta E_{\text{ov}} > 6 \text{ eV}$) oxygen vacancy formation energies. Filtering out the data points in Fig. 8(b) that do not satisfy S_3 yields the optimal Hubbard parameters $U = 2.575 \text{ eV}$, $c_1 = 0.752$ and $c_2 = -0.486$. The approximate similarity is noted of our optimised Ti 3d Hubbard projector with that determined by Jakob and Oberhofer for bulk rutile TiO_2 , defined by $c_1 = 0.828$ and $c_2 = -0.561$, using a first-principles generalised LR-cDFT method in FHI-aims.⁵⁷

3.2.3 Defect energies and computational cost vs. hybrid-DFT. Simulations of stoichiometric bulk anatase and rutile TiO_2 , as listed in Table 1, show DFT+ U simultaneously predicts both target properties, E_{bg} and V_0 , with superior accuracy than DFT, relative to experimental references.

The hybrid-DFT-predicted V_0 is closest to the experimental value, although hybrid-DFT significantly overestimates E_{bg} . DFT+ U predicts a smaller ΔE_{form} than DFT, hybrid-DFT and experiment, although all computational methods maintain a similar relative difference between ΔE_{form} for anatase and rutile TiO_2 , with $\Delta E_{\text{form}}^{\text{anatase}} - \Delta E_{\text{form}}^{\text{rutile}}$ values of -0.02 eV , -0.01 eV

and -0.01 eV for DFT, DFT+ U and hybrid-DFT, respectively. The DFT+ U -predicted covalency of TiO_2 is also suppressed compared to hybrid-DFT, as evidenced by the reduced total Ti 3d orbital occupancy, *i.e.*, $\text{Tr}[\mathbf{n}(\text{Ti 3d})]$, whilst the DFT+ U -predicted total O 2p orbital occupancy, given by $\text{Tr}[\mathbf{n}(\text{O 2p})]$, remains close to that of hybrid-DFT.

Next, self-consistent DFT+ U simulations were performed for anatase and rutile TiO_2 containing an oxygen vacancy and the substitutional dopants Nb, W, Au, Pd, Pt, Co and Mn. Table 2 summarises the success or failure of these simulations, both with or without a refined Ti 3d Hubbard projector and with or without the Hubbard parameters satisfying the error correction constraint derived from S_3 in the SI Section S2.1.2.

Comparing the rows in Table 2 that use the same Ti 3d Hubbard U value but a different Ti 3d Hubbard projector shows that refining the Hubbard projector has a direct effect on enabling self-consistent defect simulations. All calculation failures were due to unphysical ground states causing the termination of calculations due to excessive polaron localisation as seen in Fig. 6(e). Refining the Ti 3d Hubbard parameters further from $U = 2.749 \text{ eV}$, $c_1 = 0.758$ and $c_2 = -0.354$ to $U = 2.575 \text{ eV}$, $c_1 = 0.752$ and $c_2 = -0.486$, using the constraint derived from the SVM boundary S_3 , gave physical



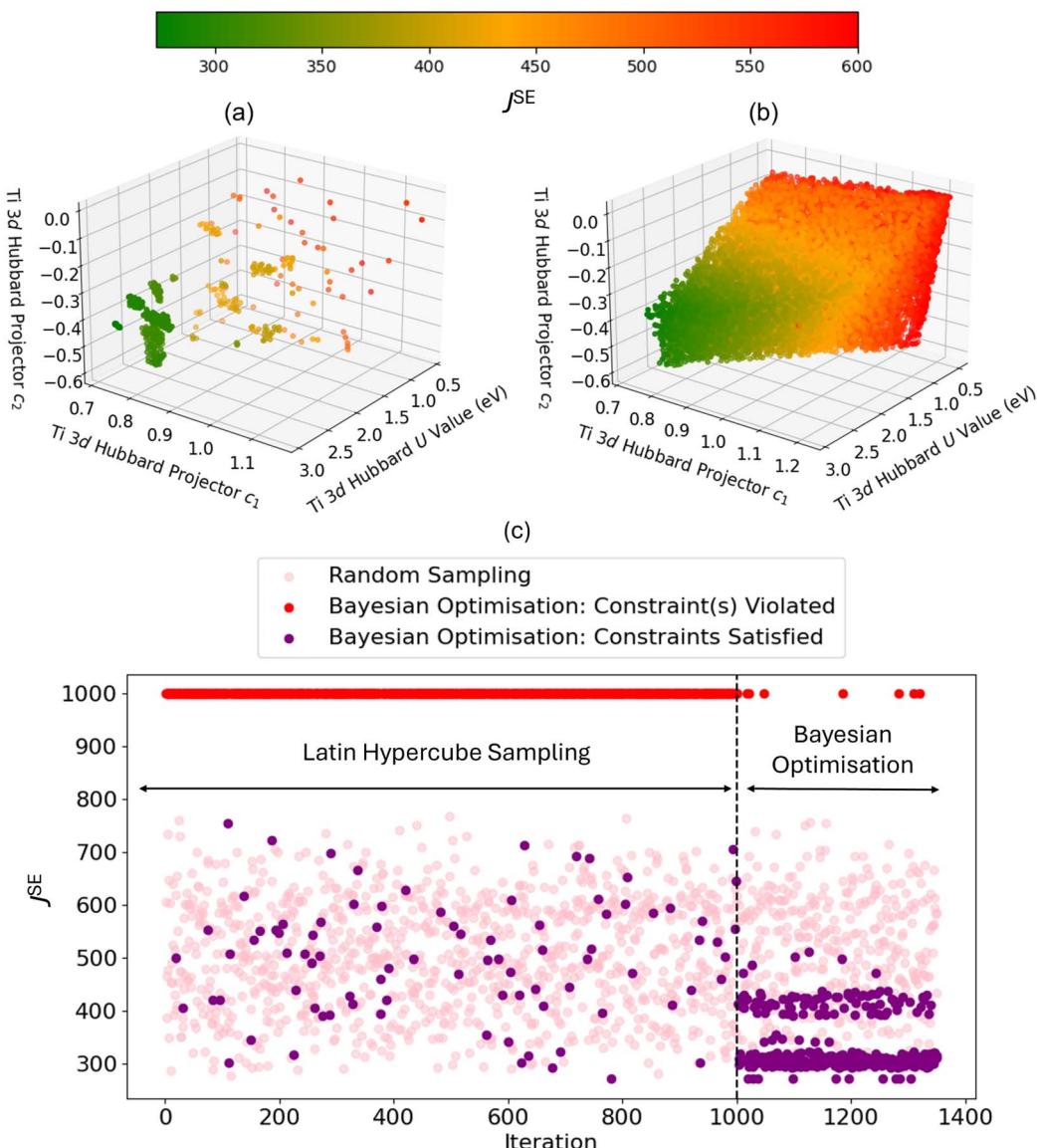


Fig. 8 The sampled Hubbard parameter space for anatase TiO_2 using (a) BO and (b) random sampling, with markers coloured according to their value of the cost function J^{SE} . Hubbard parameters that violate the constraints on $Tr[n(Ti\ 3d)]^{SISSO}$, $Tr[n(O\ 2p)]^{SISSO}$, S_1 and S_2 are excluded. (c) The distribution of values of J^{SE} corresponding to the 1350 sampled Hubbard parameters using BO (red and purple markers) and the results of the first 1350 iterations using random sampling (pink markers). In BO, the prior is trained using evaluations of 1000 randomly sampled Hubbard parameters selected using Latin Hypercube Sampling. During BO, any sampled Hubbard parameters that result in constraint violation are assigned a value of $J^{SE} = 1000$. After 1000 iterations, BO is performed for 350 iterations to efficiently optimise U , c_1 and c_2 .

defect energies for all studied defects in anatase and rutile TiO_2 , as illustrated in Fig. 9(a). Comparing the DFT-, DFT+ U - ($U = 2.575$ eV, $c_1 = 0.752$ and $c_2 = -0.486$) and hybrid-DFT predicted defect energies, the DFT+ U -predicted ΔE_{OV} in anatase (5.42 eV) and rutile (5.48 eV) are both much closer to the corresponding values computed using hybrid-DFT (5.29 and 5.76 eV, respectively) than those computed using DFT (4.44 and 4.43 eV, respectively). Without the application of a Hubbard correction to the dopant atom d orbitals, there was no obvious trend in the raw DFT+ U -predicted substitutional defect energies when

compared to hybrid-DFT. However, when normalised with respect to ΔE_{OV} in the same TiO_2 polymorph, the DFT+ U -predicted values of ΔE_{defect} were closer to the corresponding hybrid-DFT-predicted values than DFT, as illustrated in Fig. 9(b), which shows the relative defect energies for Pt- and Pd-doped anatase and rutile TiO_2 computed using DFT, DFT+ U and hybrid-DFT (single point calculations using the DFT+ U geometry). The blue columns in Fig. 9(c) plot the cost of the hybrid-DFT single-point calculation in core-hours per atom, relative to the cost of the DFT+ U geometry optimisation. For the four

Table 1 Geometric, electronic and energetic properties of bulk anatase and rutile TiO_2 , predicted using DFT (mBEEF density functional), DFT+ U (mBEEF density functional, $U = 2.575$ eV, $c_1 = 0.752$ and $c_2 = -0.486$) and hybrid-DFT (PBE0 density functional), presented alongside experimental references: band gap (E_{bg} , eV), unit cell equilibrium volume (V_0 , \AA^3), formation energy (ΔE_{form} , eV per atom), Ti 3d occupation matrix trace ($\text{Tr}[\mathbf{n}(\text{Ti 3d})]$), O 2p occupation matrix trace ($\text{Tr}[\mathbf{n}(\text{O 2p})]$)

TiO_2 polymorph	Method	E_{bg} (eV)	V_0 (\AA^3)	ΔE_{form} (eV per atom)	$\text{Tr}[\mathbf{n}(\text{Ti 3d})]$	$\text{Tr}[\mathbf{n}(\text{O 2p})]$
Anatase	DFT	2.54	137.26	-3.28	1.18	4.91
Anatase	DFT+ U	2.75	137.09	-3.02	0.69	4.64
Anatase	Hybrid-DFT	4.29	135.49	-3.21	1.25	4.66
Anatase	Experiment	3.20 (ref. 64)	136.28 (ref. 65)	-3.24 (ref. 87)	N/A	N/A
Rutile	DFT	2.21	63.50	-3.26	1.17	4.95
Rutile	DFT+ U	2.42	62.51	-3.01	0.68	4.63
Rutile	Hybrid-DFT	4.05	62.39	-3.20	1.23	4.69
Rutile	Experiment	3.00 (ref. 64)	62.44 (ref. 65)	-3.26 (ref. 87)	N/A	N/A

Table 2 The effect of Hubbard U value and projector modification on the numerical stability of point defect calculations in TiO_2 . Ticks (crosses) correspond to successful convergence (calculation termination) of self-consistent calculations using the OMR method. The satisfaction of constraints derived from the SVM boundaries S_1 , S_2 and/or S_3 affects the predicted defect energies corresponding to each set of Hubbard parameters, as shown in Fig. 9(a)

Polymorph	U (eV)	c_1	c_2	Satisfied constraints	Point defect							
					V_O^\times	$\text{Nb}_\text{Ti}^\times$	$\text{W}_\text{Ti}^\times$	$\text{Au}_\text{Ti}^\times$	$\text{Pd}_\text{Ti}^\times$	$\text{Pt}_\text{Ti}^\times$	$\text{Co}_\text{Ti}^\times$	$\text{Mn}_\text{Ti}^\times$
Anatase	2.749	1	0	None	✗	✗	✗	✗	✗	✗	✗	✗
Anatase	2.575	1	0	None	✗	✗	✗	✗	✓	✓	✓	✓
Anatase	2.749	0.758	-0.354	S_1, S_2	✓	✓	✓	✓	✓	✓	✓	✓
Anatase	2.575	0.752	-0.486	S_1, S_2, S_3	✓	✓	✓	✓	✓	✓	✓	✓
Rutile	2.749	1	0	None	✗	✗	✗	✓	✓	✓	✓	✓
Rutile	2.575	1	0	None	✗	✗	✗	✓	✓	✓	✓	✓
Rutile	2.749	0.758	-0.354	S_1, S_2	✓	✓	✓	✓	✓	✓	✓	✓
Rutile	2.575	0.752	-0.486	S_1, S_2, S_3	✓	✓	✓	✓	✓	✓	✓	✓

systems presented in Fig. 9(b), DFT+ U with geometry optimisation is between 79–189 \times faster than the hybrid-DFT single-point calculations.

3.2.4 Electron polarons in anatase vs. rutile TiO_2 . DFT+ U using $U = 2.575$ eV, $c_1 = 0.752$ and $c_2 = -0.486$ can be used to simulate experimentally observed differences in electron polaron formation in anatase vs. rutile TiO_2 , demonstrating the impact of our parameterisation work. For example, DFT+ U predicts the polymorph-dependent formation of small Holstein electron polarons in W-doped TiO_2 , characterised by strong electron–lattice interactions that results in a localised state within the TiO_2 band gap.^{10,67} This is shown in Fig. 10, where the formation of a localised W 5d_{z²} state within the rutile TiO_2 band gap is increasingly formed by incrementing the level of theory from DFT in Fig. 10(a), to DFT+ U in Fig. 10(b) and hybrid-DFT in Fig. 10(c).

The degree of defect state localisation in W-doped rutile TiO_2 , given by the energy gap between the localised state and the TiO_2 conduction band minimum, is predicted as 0.46 eV using DFT+ U and 1.76 eV using hybrid-DFT. As illustrated by the charge density isosurfaces of the highest occupied molecular orbital (HOMO) predicted by DFT in Fig. 10(d) and DFT+ U in Fig. 10(e), DFT predicts both W 5d and Ti 3d states to be delocalised, *i.e.*, predicting W⁶⁺ formation, whilst DFT+ U predicts a hybridised defect state of W 5d and Ti 3d character, indicating

the predicted formation of W⁵⁺. Similarly, DFT+ U simulations of Nb-doped rutile TiO_2 predict a Nb 4d signature at the Fermi level that is 5.5 \times larger than that in Nb-doped anatase TiO_2 . The results support previous work using EPR spectroscopy to characterise the formation of paramagnetic Nb⁴⁺ and W⁵⁺ in doped rutile TiO_2 , which is recoverable using self-consistent DFT+ U as opposed to standalone DFT or constrained DFT+ U using OMC.⁶⁷

More generally, the DFT+ U simulations reveal clear differences in the electronic structures of substitutionally doped anatase and rutile TiO_2 , particularly in the occupancies of the dopant atom d orbitals, as illustrated in Fig. 11(a). In rutile TiO_2 , there are greater occupancies of the dopant atom e_g orbitals ($m = 0$ and 2)⁶⁰ than in anatase, indicating a structural and electronic environment that favours the filling of orbitals aligned along the metal–oxygen bonds. Conversely, substitutionally doped anatase TiO_2 shows increased occupancies of the dopant atom t_{2g} orbitals ($m = -2, -1$ and 1)⁶⁰ reflecting a local electronic environment that favours the filling of orbitals aligned between the metal–oxygen bonds. The formation of localised *vs.* delocalised defect states is directly affected by the filling of the e_g and t_{2g} orbitals, respectively, leading to polymorph-sensitivity in the electrical conductivity and chemical reactivity of TiO_2 -based materials.⁶⁷ Localised defect states within the TiO_2 band gap (or present at the valence or conduction band edges), as observed for Nb- and W-doped



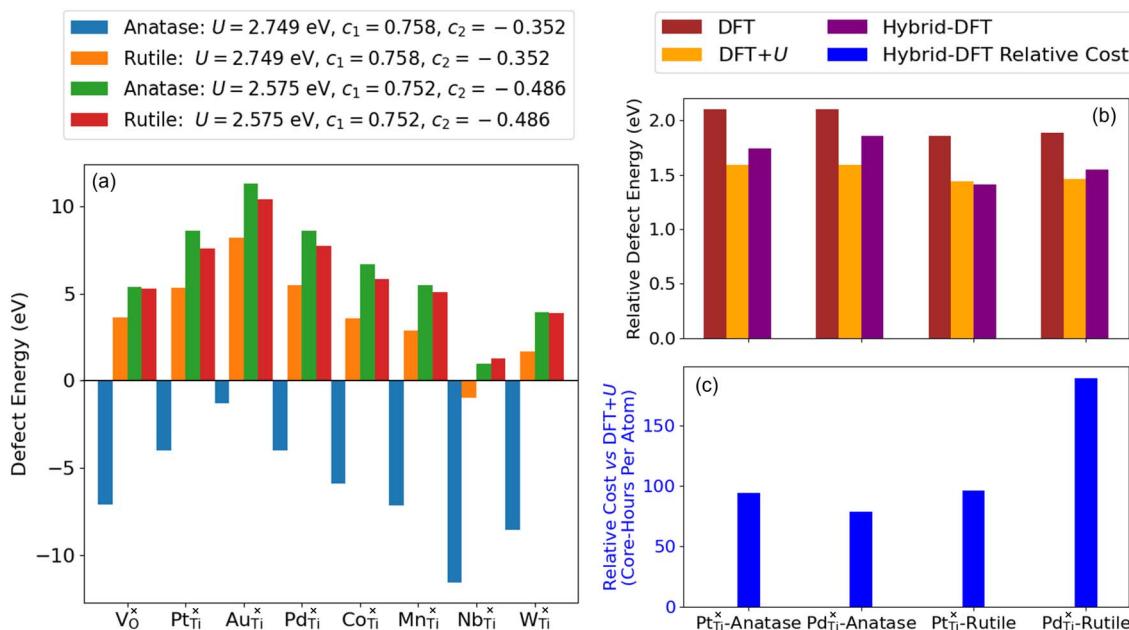


Fig. 9 (a) DFT+U-predicted values of ΔE_{OV} and ΔE_{defect} using a refined set of Hubbard parameters that satisfy the constraints derived from the SVM boundaries S_1 and S_2 , calculated using the mBEEF density functional, $U = 2.749$ eV, $c_1 = 0.758$ and $c_2 = -0.354$ vs. Hubbard parameters that satisfy the constraints derived from the SVM constraints S_1 , S_2 and S_3 , calculated using the mBEEF density functional, $U = 2.575$ eV, $c_1 = 0.752$ and $c_2 = -0.486$. (b) ΔE_{defect} relative to ΔE_{OV} for Pt- and Pd-doped anatase and rutile TiO_2 , calculated using geometry optimisation with DFT and DFT+U (mBEEF density functional, $U = 2.575$ eV, $c_1 = 0.752$ and $c_2 = -0.486$) and single-point calculations using hybrid-DFT (PBE0 density functional, using the DFT+U-optimised geometry). (c) The cost of the hybrid-DFT single point calculations relative to the DFT+U geometry optimisations in core-hours per atom.

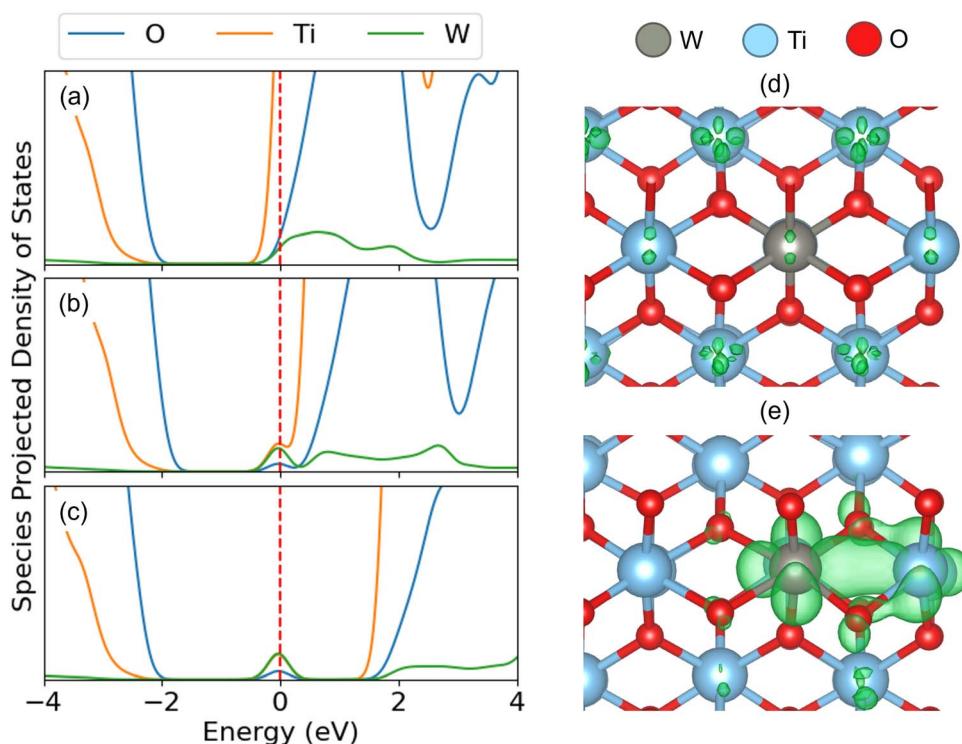


Fig. 10 The elemental species projected density of states for W-doped rutile TiO_2 , calculated using (a) DFT (mBEEF density functional), (b) DFT+U (mBEEF density functional, $U = 2.575$ eV, $c_1 = 0.752$ and $c_2 = -0.486$) and (c) hybrid-DFT (PBE0 density functional single point calculation using the DFT+U optimised geometry). The Fermi level is denoted by the red dashed line. The corresponding charge density isosurfaces for the highest occupied molecular orbital (HOMO), at the 0.025 e \AA^{-3} level, are shown for (d) DFT and (e) DFT+U.



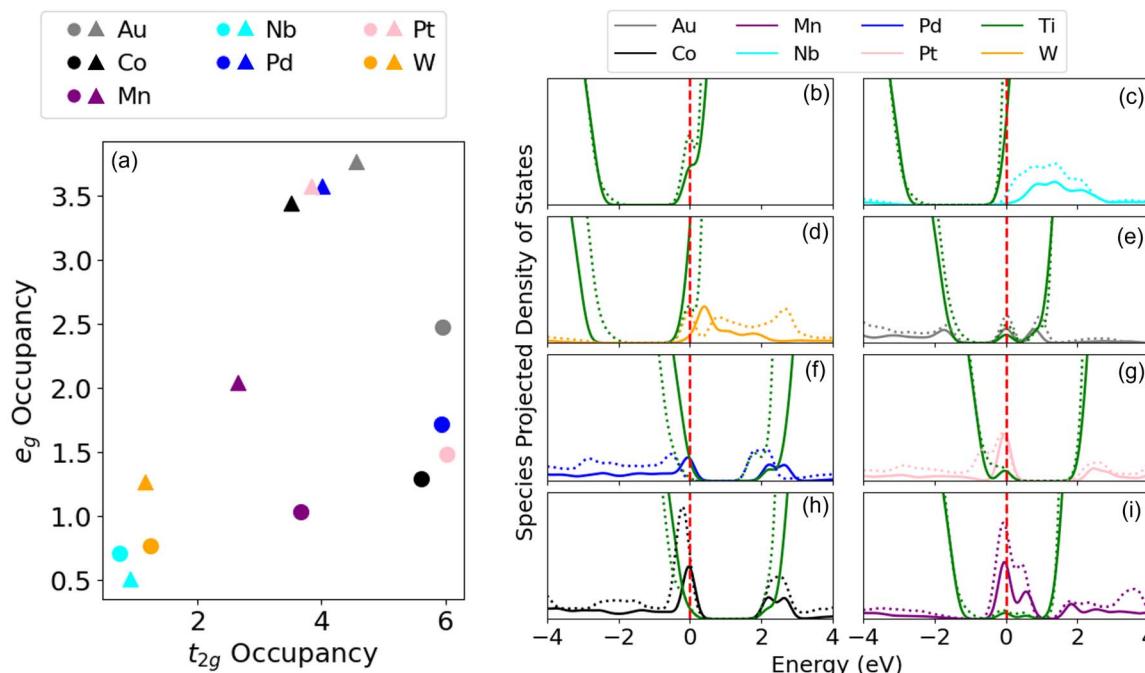


Fig. 11 The DFT+ U -predicted (a) occupancies of the dopant atom t_{2g} and e_g orbitals, in the 3d, 4d or 5d subshell, for all extrinsic defects in anatase (circles) and rutile (triangles), calculated using the mBEEF density functional, $U = 2.575$ eV, $c_1 = 0.752$ and $c_2 = -0.486$. The corresponding elemental species projected density of states for (b) V_O^\times , (c) $\text{Nb}_\text{Ti}^\times$, (d) $\text{W}_\text{Ti}^\times$, (e) $\text{Au}_\text{Ti}^\times$, (f) $\text{Pd}_\text{Ti}^\times$, (g) $\text{Pt}_\text{Ti}^\times$, (h) $\text{Co}_\text{Ti}^\times$, (i) $\text{Mn}_\text{Ti}^\times$ in bulk anatase (solid lines) and rutile (dashed lines) TiO_2 , are normalised with respect to the different defect concentrations in the anatase and rutile simulation supercells. The Fermi level is denoted by the red dashed line.

rutile in Fig. 11(c) and (d), respectively, and both TiO_2 polymorphs containing an oxygen vacancy and Au, Pd, Pt, Co and Mn dopants in Fig. 11(b), (e)–(i), respectively, give rise to electronic conduction *via* thermally activated polaron hopping (conductivity increases with temperature) and provide readily available sites for activating reactant molecules.^{92,93} Conversely, delocalised defect states located deeper in the valence or conduction bands, as observed for Nb- and W-doped anatase in Fig. 11(c) and (d), respectively, give rise to improved electronic conductivity according to a band-like model and can both reduce the degrading recombination of electrons and holes in solar cells and lower the rate determining step of the oxygen evolution reaction on rutile TiO_2 surfaces.^{94,95}

3.3 Optimising Hubbard U values and projectors from first-principles

3.3.1 Motivation and method reconfiguration. Following the success of the semi-empirical machine learning approach in mitigating numerical instability during simulations of defects in TiO_2 (Section 3.2), we now turn to the development of a fully first-principles strategy for optimising Hubbard U values and projectors. Simultaneous optimisation of Hubbard U values and projectors is particularly attractive as a step towards the long-term goal of formulating DFT+ U as a true density functional, in which both the correlated subspace and the on-site Coulomb repulsion are optimally defined by the electron density and orbitals of a material. However, the reformulation of the semi-

empirical machine learning approach is contingent on two major modifications. Firstly, it is necessary to redefine the semi-empirical cost function (J^{SE}) by removing all experimental reference data, but in a manner that will ultimately yield similar results leading to the numerically stable self-consistent defect calculations in Section 3.2.3. Secondly, the termination and SCF non-convergence of defect calculations observed for TiO_2 were also observed for a broad range of TMOs and REOs; therefore, it is necessary to generalise the SVM constraints in Section 3.2 in order to filter out Hubbard parameters that lead to unstable defect calculations for systems beyond TiO_2 .

To investigate how best to construct a first-principles cost function (J^{FP}), the DFT+ U -predicted Ti 3d and O 2p orbital occupancies in anatase and rutile TiO_2 , using a refined and atomic Ti 3d Hubbard projector, were compared with the occupancies calculated using hybrid-DFT, as illustrated in Fig. 12. Fig. 12(a) and (c) show that DFT+ U using an atomic Ti 3d Hubbard projector predicts Ti 3d orbital occupancies closer to those calculated using hybrid-DFT, although this is expected as the hybrid-DFT-calculated occupancies are derived from the atomic Ti 3d Hubbard projector and so cannot be compared in a like-for-like manner to those derived from a modified Hubbard projector (detailed in the SI Section S1.3). Fig. 12(b) and (d) show that DFT+ U using the refined Ti 3d Hubbard projector predicts O 2p orbital occupancies closer to those predicted using hybrid-DFT, with errors $<5\%$ for all values of m , which is a like-for-like comparison as the O 2p orbital occupancies are derived



from the atomic O 2p Hubbard projector across all methods (detailed in the SI Section S1.3). The first-principles cost function was therefore defined as the average error in the DFT+U-predicted O 2p orbital occupancies *vs.* hybrid-DFT (defined in Section 2.3.1), which is obtained from a single reference calculation of a geometry optimised unit cell. To investigate the requirement for SVM constraints in a first-principles approach for optimising Hubbard U values and projectors, the dataset for classifying the validity of bulk oxygen vacancy calculations in anatase TiO_2 (Fig. 12(e)) was considered again in terms of percentage errors of $\text{Tr}[\mathbf{n}(\text{Ti } 3\text{d})]$ and $\text{Tr}[\mathbf{n}(\text{O } 2\text{p})]$ *vs.* hybrid-DFT (Fig. 12(f)). Fig. 12(f) shows that minimising J^{FP} towards zero is necessary but not a sufficient condition to ensure the numerical stability of point defect calculations in anatase TiO_2 , highlighting the requirement of satisfying SVM-derived constraints as well as minimising J^{FP} for accurate Hubbard parameter optimisation.

In the following sections, we outline the generalisation of both the regression and classification methods adopted in Section 3.2, extending them towards the development of a single unified model that can automatically parameterise Hubbard U values and projectors from material-dependent inputs, *i.e.*, in the spirit of a foundation model for DFT+U parameterisation. This serves as a test of how well the insights gained from TiO_2 transfer across chemical space, with the ultimate goal of enabling accurate, self-consistent simulations of defects and polarons across a broad range of TMOs and

REOs. We note that such a framework could equally be formulated as an iterative active learning scheme for systems that are difficult to incorporate within a single unified model, as outlined in Section 4.2.

3.3.2 Generalised symbolic regression. Estimating the DFT+U-predicted O 2p occupancies was achieved using three HI-SISSO correlations, which were constructed using the expanded primary feature set of Hubbard parameters, basis set parameters, DFT predicted orbital occupancies and atomic material descriptors (listed in the SI Section S2.2.1), before searching the landscape of J^{FP} _{predicted} for the ten materials listed in Table S2 in the SI Section S1.3, using the corresponding material-dependent descriptors and hybrid-DFT reference orbital occupancies. The outputs of the linear search were families of solutions for each material (discussed in the SI Section S2.2.2), of which 94 combinations of U , c_1 and c_2 were validated using DFT+U to compare the accuracy of the J^{FP} _{predicted} values (using the HI-SISSO correlations) *versus* J^{FP} _{validated} values (from DFT+U calculations), achieving an average MAE across all materials of 5.02% in Fig. 13(a).

To investigate the relationship between the residuals in Fig. 13(a) and the size of the training set per material, the MAE was compared with D_M (both averaged per material) to quantify whether Hubbard projector optimisation is interpolative or extrapolative. As illustrated in Fig. 13(b), the generalised approach is more interpolative for anatase TiO_2 , rutile TiO_2 and ZrO_2 , which have the three smallest values of D_M . Large values

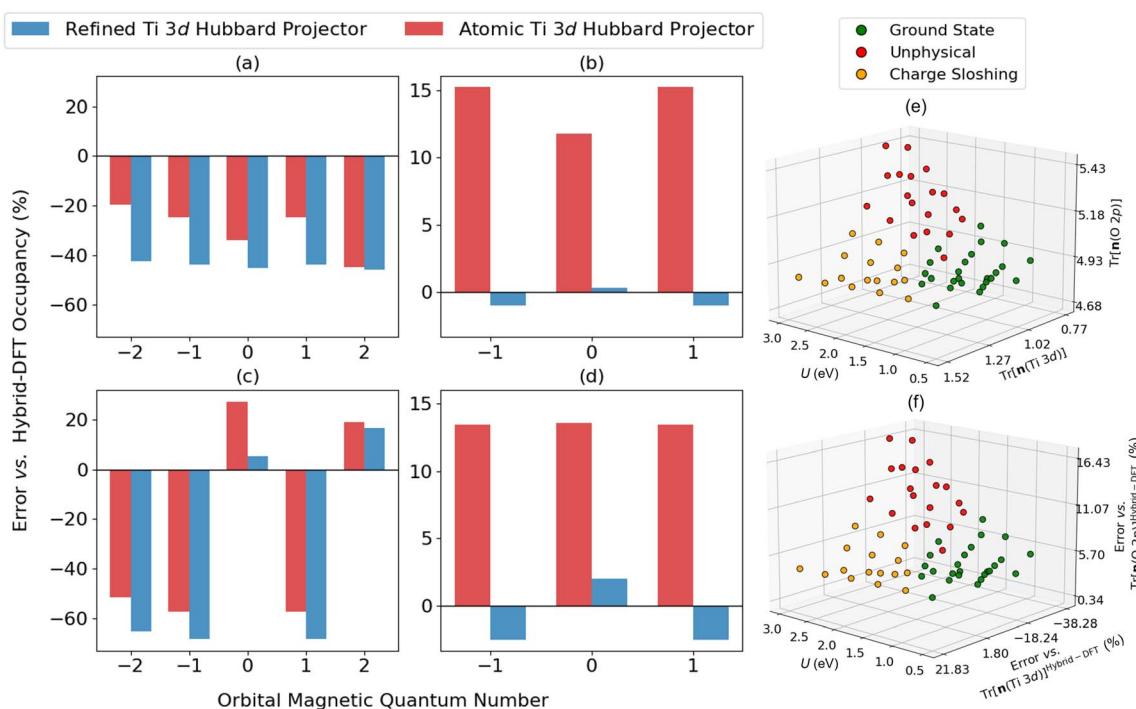


Fig. 12 Comparing the percentage errors of the DFT+U-predicted Ti 3d and O 2p orbital occupancies in anatase and rutile TiO_2 *vs.* hybrid-DFT (PBE0 density functional); (a) Ti 3d in anatase TiO_2 , (b) O 2p in anatase TiO_2 , (c) Ti 3d in rutile TiO_2 and (d) O 2p in rutile TiO_2 . Blue bars correspond to DFT+U using the mBEEF density functional, $U = 2.575$, $c_1 = 0.752$ and $c_2 = -0.486$. Red bars correspond to DFT+U using the mBEEF density functional, $U = 2.575$, $c_1 = 1$ and $c_2 = 0$. The same outcomes of bulk oxygen vacancy calculations plotted in Fig. 7 are plotted in (e) and (f), where (e) is plotted in terms of the raw U , $\text{Tr}[\mathbf{n}(\text{Ti } 3\text{d})]$ and $\text{Tr}[\mathbf{n}(\text{O } 2\text{p})]$ values, whilst (f) is plotted in terms of U and the percentage errors of $\text{Tr}[\mathbf{n}(\text{Ti } 3\text{d})]$ and $\text{Tr}[\mathbf{n}(\text{O } 2\text{p})]$ *vs.* hybrid-DFT.



of D_M , as seen for CeO_2 , Cu_2O and LiCoO_2 , indicate the generalised approach is comparatively extrapolative for these materials. As there is no correlation between the MAE and D_M , the larger residuals in Fig. 13(a) for ZrO_2 and MoO_3 do not appear to be related to the training set size and are likely due to the choice of primary features used in HI-SISSO, such as the lack of structure-dependent features, and requires further study to enhance the method transferability.

3.3.3 Generalised symbolic classification. Given that the minimisation of J^{FP} is necessary but not sufficient for numerically stable point defect calculations in TiO_2 , as illustrated in Fig. 12(f), the constraints on the DFT+ U -predicted covalency established in Fig. 7 needed to be generalised across materials. Generalised constraints were determined using the primary features U and J^{FP} , as well as two additional material-dependent descriptors of covalency, including the average error in the DFT+ U -predicted metal d or f orbital occupancies compared to hybrid-DFT (E^{metal}) and the ratio of the traces of the metal d or f and O 2p occupation matrices predicted using hybrid-DFT (R^{hybrid}), as defined in Section 2.3.2. With the primary features U , J^{FP} , E^{metal} and R^{hybrid} , generalised classification was performed to predict the same outcomes shown in Fig. 7 for bulk oxygen vacancy calculations, but across TiO_2 , CeO_2 , ZrO_2 , MoO_3 , WO_3 and Cu_2O , as illustrated in Fig. 14(a) and (b), where the unitless SVM boundaries S_4 and S_5 are defined in the SI Section S2.2.1 and the constant $\alpha = 1 \text{ eV}^{-1}$ is introduced to ensure dimensional consistency. S_4 and S_5 are then combined to form a constraint on the generalised Hubbard parameter space, to ensure the numerical stability of point defect calculations using the OMR method:

$$S_4 \geq 0 \wedge S_5 \geq 0 \quad (15)$$

3.3.4 Electron and hole polarons in $\text{LiCo}_{1-x}\text{Mg}_x\text{O}_{2-x}$. The generalised regression and classification models were then integrated to perform a one-shot screening of the Hubbard parameter space for a previously unseen material, to test the accuracy and numerical stability of DFT+ U simulations of the stoichiometric and defective electronic structure. We chose the common Li-ion battery cathode material LiCoO_2 , which is the focus of wide-ranging studies to enhance its electrochemical properties, such as electrical conductivity and long-term cycling stability, *via* the introduction of low-valence ions resulting in charge compensation from the formation of point defects.⁹⁶⁻⁹⁸ For example, substitution of Co^{3+} in LiCoO_2 with Mg^{2+} is proposed to result in the formation of Co^{4+} holes, that exist delocalised⁹⁹⁻¹⁰¹ and are attributed to the $100\times$ enhanced electrical conductivity of $\text{LiCo}_{1-x}\text{Mg}_x\text{O}_2$ compared to pristine LiCoO_2 .¹⁰² Other reports suggest that charge compensation and enhancements in electrical conductivity occur *via* the formation of oxygen vacancies, whilst Mg doping does not cause a change in the oxidation state of Co atoms.^{99,103}

Literature reported DFT+ U studies, in a planewave basis, have yet to provide an unambiguous rationale for the increased electrical conductivity of Mg-doped LiCoO_2 , with significant sensitivity of the DFT+ U -predicted localisation of Co^{4+} holes with respect to the choice of Hubbard parameters. For example, DFT+ U using a Co 3d Hubbard U value determined from first-principles using LR-cDFT (between 4.91 eV to 5.62 eV) predicts deep Co 3d defect states within the LiCoO_2 band gap,

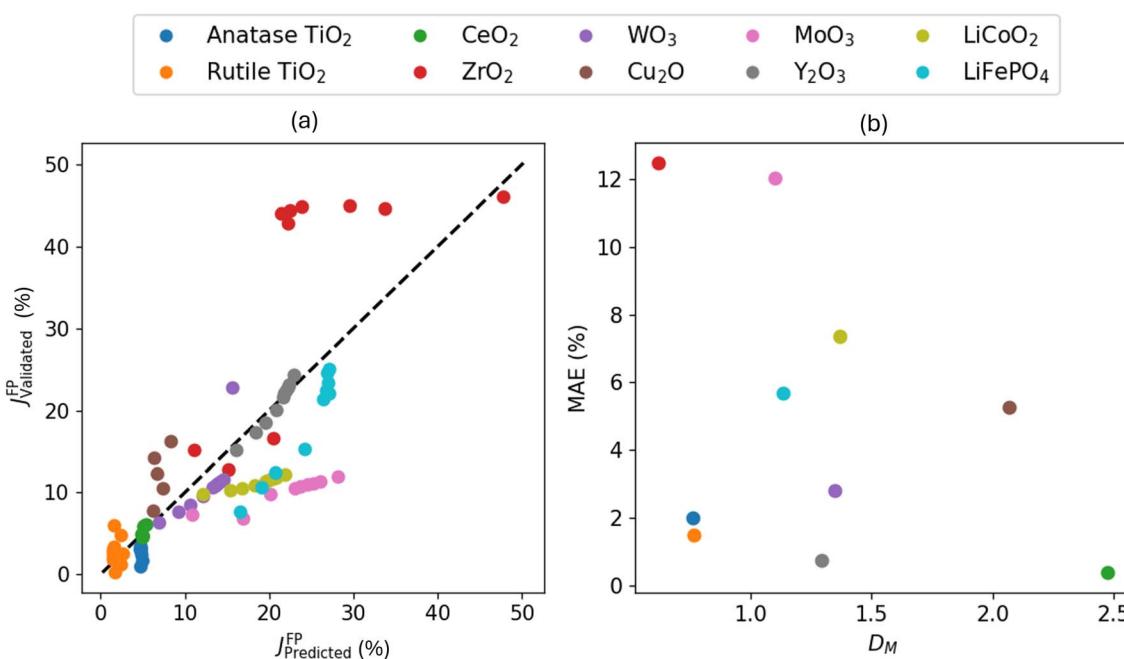


Fig. 13 (a) Parity plot of the HI-SISSO-predicted ($J^{\text{FP}}_{\text{predicted}}$) and DFT+ U -validated ($J^{\text{FP}}_{\text{validated}}$) cost function across ten TMOs and REOs using the generalised approach. (b) Comparison of the MAE of $J^{\text{FP}}_{\text{predicted}}$ for each material in (a) vs. the corresponding Mahalanobis distance (D_M), averaged over all tested combinations of Hubbard parameters, to visualise the dependence of the accuracy of the generalised approach on the training set size for each material.



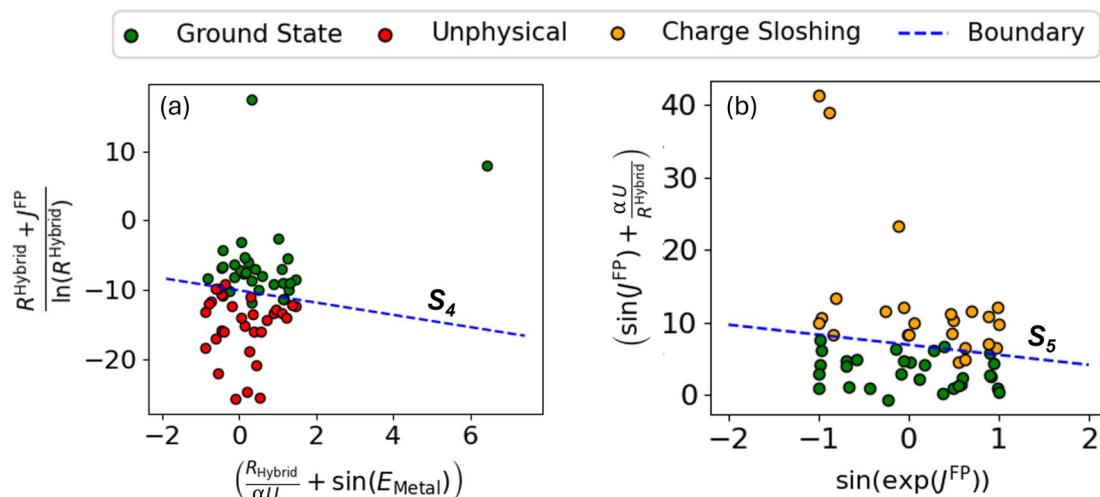


Fig. 14 The linear boundaries (a) S_4 and (b) S_5 that classify the numerical stability of DFT+ U simulations of a bulk oxygen vacancy in TiO_2 , CeO_2 , ZrO_2 , MoO_3 , WO_3 and Cu_2O , separating regions in the DFT+ U -computed feature space that lead to successful convergence, termination due to an unphysical ground state, and charge sloshing that prevents SCF convergence.

which is inconsistent with the experimentally observed high electrical conductivity of $\text{LiCo}_{1-x}\text{Mg}_x\text{O}_2$, whilst DFT+ U using smaller Hubbard U values predicts shallow defect states, supporting the experimental observations.^{5,104} Whilst no explanation for the sensitivity of DFT+ U simulations of $\text{LiCo}_{1-x}\text{Mg}_x\text{O}_2$ was given, Hoang and Johannes used DFT+ U to simulate the self-trapping of Ni^{4+} holes in LiNiO_2 , where the DFT+ U -predicted instability of Ni^{4+} was attributed to the predicted O 2p character of the LiNiO_2 valence band edge, highlighting the

importance of considering band edge effects when choosing appropriate Hubbard parameters.¹⁰⁵

To test the DFT+ U -predicted localisation of hole polarons in $\text{LiCo}_{1-x}\text{Mg}_x\text{O}_2$ in a NAO framework, the one-shot approach was first applied to determine an appropriate Co 3d Hubbard U value and projector for stoichiometric LiCoO_2 . The parameters were determined using a linear search of the HI-SISSO-predicted cost function ($J_{\text{predicted}}^{\text{FP}}$) for U between 0 eV and 5 eV, c_1 between 0.5 and 1 and c_2 between 0 and -0.6, before all

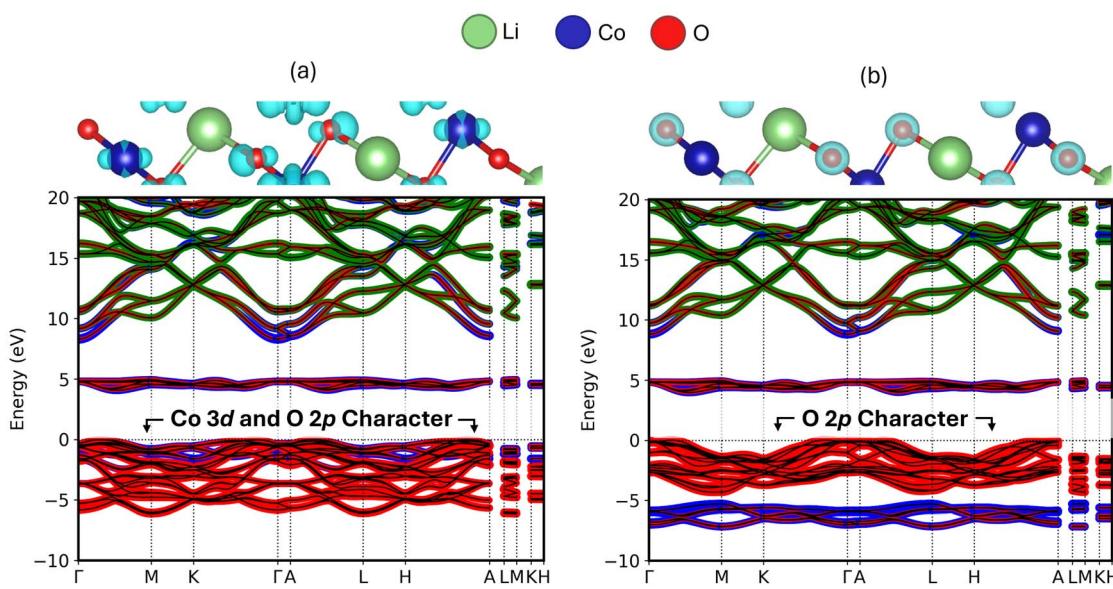


Fig. 15 Charge density isosurface at the $0.05 \text{ e}^- \text{ A}^{-3}$ level for the eigenstate corresponding to the HOMO and the corresponding Mulliken-projected band structure for stoichiometric LiCoO_2 along the high-symmetry \mathbf{k} -point path Γ -M-K- Γ -A-L-H-A-L-M-K-H, calculated using (a) DFT+ U with the mBEEF density functional, $U = 3.342 \text{ eV}$, $c_1 = 0.792$ and $c_2 = -0.506$ and (b) DFT+ U with the mBEEF density functional, $U = 3.342 \text{ eV}$, $c_1 = 1$ and $c_2 = 0$. Marker sizes and colours in the band structure plots correspond to the relative contribution for that species to the band. The valence band edge character is either (a) a mixture of Co 3d and O 2p states or (b) dominated by O 2p states. The band structure plots are centred with respect to the Fermi level.



Hubbard parameters that violate eqn (15) were discarded. The output of this initial screening is a region of the Hubbard parameter space (U , c_1 and c_2) that minimises $J_{\text{predicted}}^{\text{FP}}$ and satisfies eqn (15) but contains multiple possible solutions. We therefore narrow this region down to three candidate Hubbard parameters for validation using K-means clustering of a reduced subset of the screened Hubbard parameter space that corresponds to the lowest 10% of $J_{\text{predicted}}^{\text{FP}}$ (illustrated in the SI Section S2.2.2).

From the three candidate Hubbard parameters determined using K-means clustering, DFT+ U using $U = 3.342, $c_1 = 0.792$ and $c_2 = -0.506$, which is henceforth referred to as “refined-DFT+ U ”, provided the best accuracy in the predicted E_{bg} (4.18 eV), V_0 (97.38 Å³) and ΔE_{form} (-2.40 eV per atom) after validating against experimental references (listed in the SI Section S2.2.2). Comparing the DFT+ U -predicted electronic structure of stoichiometric LiCoO₂ using refined-DFT+ U and $U = 3.342, $c_1 = 1$ and $c_2 = 0$ (*i.e.*, the same Co 3d Hubbard U value with an atomic projector, which is henceforth referred to as “atomic-$$

DFT+ U'), projector refinement was found to be essential to predict the mixed Co 3d and O 2p valence band edge character of LiCoO₂ in Fig. 15(a), which is also predicted using hybrid-DFT and reported experimentally.¹⁰⁶ Conversely, DFT+ U using atomic-DFT+ U , or a much larger Hubbard U value than in Fig. 15(a), both predict the LiCoO₂ valence band edge to be dominated by O 2p states, as illustrated in Fig. 15(b).

The defective LiCoO₂ bulk containing Mg_{Co}^X was simulated using both refined-DFT+ U and atomic-DFT+ U , using the OMR method with the 3d_{z²} orbital occupancy of the Co atom nearest the Mg dopant reduced by 1 to initialise Co⁴⁺. In both simulations, SCF convergence and geometry optimisation completed successfully without termination or charge sloshing. Both simulations also predict the formation of shallow defect states at the top of the valence band in Fig. 16(b), corresponding to a delocalised hole polaron that exists hybridised between Co 3d and O 2p states using refined-DFT+ U in Fig. 16(d), compared to non-hybridised across only O atoms using atomic-DFT+ U in Fig. 16(e). These differences in the DFT+ U -predicted character

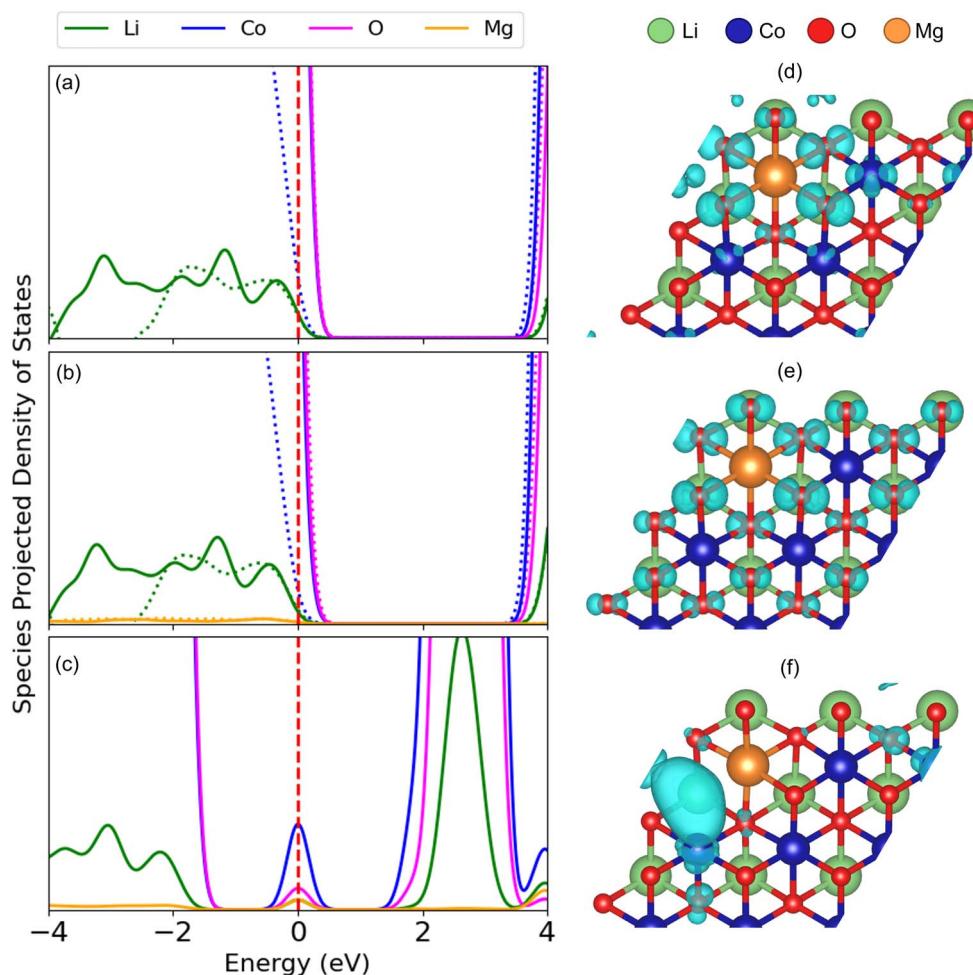


Fig. 16 Elemental species projected density of states for (a) stoichiometric LiCoO₂, (b) defective LiCoO₂ containing Mg_{Co}^X and (c) defective LiCoO₂ containing both Mg_{Co}^X and V_O^X, calculated using DFT+ U with the mBEEF density functional, $U = 3.342, $c_1 = 0.792$ and $c_2 = -0.506$ (refined-DFT+ U , solid lines) and DFT+ U with the mBEEF density functional, $U = 3.342, $c_1 = 1$ and $c_2 = 0$ (atomic-DFT+ U , dotted lines). All plots are relative to the Fermi level (red dashed line). The corresponding charge density isosurfaces at the 0.025 e Å⁻³ level for the eigenstate corresponding to the HOMO are shown for defective LiCoO₂ containing Mg_{Co}^X, calculated using (d) refined-DFT+ U and (e) atomic-DFT+ U , as well as (f) defective LiCoO₂ containing both Mg_{Co}^X and V_O^X, calculated using refined-DFT+ U .$$



of the hole polaron also directly affect their stability, with $\Delta E_{\text{defect}} = 1.48$ eV using refined-DFT+U and $\Delta E_{\text{defect}} = 10.89$ eV using atomic-DFT+U. Given that compositions with a 1:1 ratio of Co and Mg, *i.e.*, $\text{LiCo}_{0.5}\text{Mg}_{0.5}\text{O}_2$, have been synthesised experimentally,¹⁰⁷ DFT+U with the default atomic Co 3d Hubbard projector therefore incorrectly predicts the total insolubility of Mg in LiCoO_2 .

Both refined- and atomic-DFT+U were further used to simulate a bulk oxygen vacancy in Mg-doped LiCoO_2 using the OMR method. Here, the nearest O atom to the Mg dopant was removed and the two nearest Co atoms to the vacancy were initialised as Co^{2+} by increasing their $3d_{yz}$ orbital occupancies by 1. With the atomic Co 3d Hubbard projector, the simulation did not converge due to charge sloshing, *i.e.*, oscillations in the charge density illustrated in the SI Section S2.2.2, similar to TiO_2 in Section 3.1.2. Conversely, DFT+U using the refined Co 3d Hubbard projector successfully converged without termination or charge sloshing, predicting a deep defect state of $3d_{x^2-y^2}$ character and an associated oxygen vacancy formation energy of $\Delta E_{\text{OV}} = 3.61$ eV. These results suggest that both Mg-doping and oxygen vacancy formation could enhance the electrical conductivity of LiCoO_2 *via* the transport of delocalised hole and localised electron polarons, respectively, whilst the generalised approach for optimising the Co 3d Hubbard U value and projector is robust with respect to numerical instability that is often observed when using the default atomic Hubbard projector. These results give promise to the development of the first-principles approach by extending the size and diversity of the training set used for generalised regression and classification.

4 Future work

Whilst we have demonstrated how supervised machine learning can be applied to simultaneously optimise Hubbard U values and projectors to improve the accuracy and numerical stability of DFT+U in a NAO framework, we note clear avenues for further research that are not accounted for in the current work.

4.1 Extension to challenging open-shell systems

The methods and results presented generally hold well for closed-shell systems or those with ions in a low-spin state. In contrast, we encountered significant challenges applying DFT+U to open-shell systems containing ions in a high spin state, *e.g.*, Co^{2+} in CoO , Mn^{4+} in MnO_2 , Fe^{3+} in Fe_2O_3 and Cr^{3+} in Cr_2O_3 . For these materials, DFT+U was found to consistently suffer from SCF non-convergence as a result of charge sloshing, *i.e.*, excessive oscillations in the charge density, which even occurred during single point calculations of small unit cells, irrespective of the chosen Hubbard U values and projectors. Upon analysing the DFT-predicted ground state electronic structures for these materials, all cases are incorrectly predicted to be metallic with zero band gap, therefore we hypothesise that the starting electronic structure from DFT makes SCF convergence for DFT+U very challenging in a NAO framework. After further testing, we find that switching to spin polarisation in

combination with meta-GGA exchange-correlation density functionals and carefully selected SCF mixing parameters can improve the DFT-predicted electronic structure to restore a bandgap (albeit which is underestimated compared to experiment). These changes make the convergence of DFT+U with refined Hubbard projectors feasible and will be the focus of a future study translating this work to defects in magnetic TMOs and REOs. Whilst this remains an unresolved challenge at the moment, we note that the restoration of semiconducting or insulating ground states from an initial DFT-predicted metallic state is routinely achievable in planewave implementations of DFT+U,¹⁰⁸ therefore a more detailed investigation into exact differences between implementations may help.

4.2 Universal models *vs.* active learning

In Section 3.3, we outline the development of a single universal model for parameterising Hubbard U values and projectors across materials. This approach served as a test for how well the insights gained from TiO_2 transfer across chemical space, with the ultimate goal of enabling accurate, self-consistent simulations of defects and polarons across a broad range of TMOs and REOs. A valid alternative approach could be an iterative active learning scheme, where U , c_1 and c_2 are progressively refined so that the DFT+U-predicted electronic structure resembles that from hybrid-DFT, *e.g.*, *via* comparison of orbital occupation numbers or band structures. This active learning approach may work well for systems that are not accurately incorporated within a single universal model, but would require repeating for different materials and incur a potentially significant cost for the total number of DFT+U calculations required. We have shown that Bayesian optimisation can efficiently sample a SISSO-derived semi-empirical cost function in Section 3.2.2, therefore this could be repurposed to iteratively perform DFT+U geometry optimisation calculations for a small unit cell, sampling Hubbard parameters and targeting orbital occupancies calculated using hybrid-DFT. If the cost function landscape is very difficult to optimise with an iterative approach, both the universal and active learning schemes could be combined, *i.e.*, the outputs from the one-shot approach used as initial positions for active learning, which may improve convergence to good solutions whilst requiring fewer DFT+U iterations.

4.3 Compatibility with high-throughput simulations

The current framework outputs several combinations of Hubbard U values and projectors, which serve as optimised candidate parameters for validation with the aim of enabling self-consistent defect simulations. Further development into a high-throughput optimisation requires an improvement in accuracy of the generalised symbolic regression model on out-of-training data, which should be feasible since this work considers a very small training set of 197 sets of DFT+U-calculated orbital occupancies from geometry optimised unit cells, of which nearly half correspond to TiO_2 . With a better extrapolative accuracy, the generalised approach could be used to output a single Hubbard parameter, rather than relying on K-means clustering to output several candidate parameters for further



validation. The reliance on small unit cells further reduces the computational overhead associated with generating corresponding hybrid-DFT reference data.

4.4 Choice of high-level reference and extension to other codes

In the current work, we chose hybrid-DFT as the high-level reference method to obtain target orbital occupancies for metal d or f and O 2p states. This choice was made in order to establish a consistent and computationally tractable benchmark against which machine learning-optimised U values and projectors could be compared. While this introduces a dependency on the choice of reference, it is entirely possible within our framework to select another level of theory depending on the target material and available computational resources. The framework could equally be extended to optimise against alternative physics-informed quantities, *e.g.*, minimising errors in band structure plots, enforcing piecewise linearity of the total energy with respect to fractional occupancy of the correlated subspace, or maximising occupation matrix idempotency. In the case of magnetic systems, for which identifying the true ground state is complicated by the presence of metastable states in the potential energy surface, one could instead target experimentally observed magnetic orderings as the optimisation criteria.

The methods presented could also be extended to other electronic structure codes, for which there already exist several schemes that require simultaneous parameter optimisation, *e.g.*, DFT+ U + V and orbital resolved DFT+ U .^{32,109} In such frameworks, rather than tuning linear expansion coefficients as in our NAO-based approach, one would instead adjust the definition of the Hubbard projector *via* the projector augmented wave (PAW) augmentation radius in a planewave basis,¹⁷ or the muffin-tin radius in a linear augmented planewave (LAPW) basis, both of which have been reported to significantly influence the predicted geometric, energetic and electronic properties of complex oxides.^{16,110} Direct adaptation of the framework for other electronic structure codes will be essential, as Hubbard parameters are generally not transferable across codes with different basis sets and definitions of the Hubbard projector. As discussed by Kick *et al.*, DFT+ U in a NAO framework typically requires U values \sim 1–2 eV smaller than other formalisms to achieve comparable charge localisation.¹⁵ The observation agrees with the results of this work concerning Ti 3d Hubbard parameters for simulating TiO₂ ($U = \sim$ 2.5–3 eV) *vs.* literature reported values computed in a real-space formalism ($U = \sim$ 5–6 eV).¹¹¹

5 Conclusions

To navigate the numerical instability of self-consistent DFT+ U simulations of TMOs and REOs, including the prediction of erroneous metallic ground states and the termination or non-convergence of point defect calculations, it is essential to carefully define an appropriate Hubbard projector. Simultaneous optimisation of the Hubbard U value and projector has

been demonstrated semi-empirically using SR and SVMs, before using BO to minimise the errors of target properties relative to experimental references. The Ti 3d Hubbard U value and projector have been semi-empirically refined to enable self-consistent DFT+ U simulations of intrinsic and extrinsic defects in both anatase and rutile TiO₂. The outcome is DFT+ U simulations with comparable accuracy to hybrid-DFT in terms of the relative stabilities of point defects and the formation of localised Holstein polarons, but at orders of magnitude lower cost. The DFT+ U -predicted occupation matrices reproduce the hybrid-DFT O 2p occupation matrix, which can be an effective cost function for a first-principles strategy for Hubbard U value and projector optimisation.

The semi-empirical approach was therefore defined as a first-principles approach and generalised across materials using hierarchical SR to screen the Hubbard parameter space using empirical correlations to learn the DFT+ U potential energy surface in terms of orbital occupancies. Predictions of metal d or f orbital and O 2p orbital occupancies were made in terms of Hubbard parameters, basis set parameters, DFT-predicted orbital occupancies and atomic material descriptors. The first-principles approach enables the development of a generalised workflow for the one-shot computation of Hubbard U values and projectors for different materials that requires no successive DFT+ U calculations, as in active learning schemes. The method transferability is demonstrated for 10 prototypical TMOs and REOs (anatase and rutile TiO₂, Cu₂O, MoO₃, WO₃, Y₂O₃, ZrO₂, CeO₂, LiCoO₂ and LiFePO₄), which each require one reference DFT and hybrid-DFT calculation as inputs, whilst generating families of solutions for each material, *i.e.*, optimised Hubbard projectors for a given Hubbard U value. Upon validating a subset of these solutions, a MAE of 5.02% for the DFT+ U -predicted O 2p orbital occupancies was achieved, with demonstrated accuracy for materials unseen from model training (LiCoO₂ and LiFePO₄).

Predicting the numerical stability of point defect calculations can also be generalised across materials using symbolic classification, using Hubbard U values and material-dependent descriptors of covalency, enabling the determination of Hubbard U values and projectors that are robust against numerical instability. The validity of Hubbard U values and projectors determined from first-principles has been investigated for the self-consistent simulation of Mg-doped and oxygen deficient LiCoO₂, where refining the Co 3d Hubbard projector enables the numerically stable simulation of experimentally reported charge compensation mechanisms driving the material's high electrical conductivity. The same results were not possible using an atomic Co 3d Hubbard projector and did not require any prior testing of suitable Co 3d Hubbard U values or projectors, which gives promise for the development of a foundational tool for simultaneously determining multiple Hubbard parameters in a NAO framework and beyond. The work demonstrates how advanced machine learning algorithms can aid the development of inexpensive and transferable workflows for DFT+ U parameterisation, achieving extrapolative accuracy beyond the limits of small training sets, for more accurate and efficient simulations of complex energy materials.



Author contributions

All authors contributed to the conceptualisation of the project and to software choices and method development in this work. AC performed the electronic structure calculations presented in this work and performed the analysis of results. All authors contributed to the preparation of the manuscript.

Conflicts of interest

There are no conflicts to declare.

Data availability

All Python scripts for global optimisation, datasets for regression/classification and input/output files for electronic structure calculations have been uploaded to the GitHub repository <https://github.com/amitmc1/Hubbardprojectors>, with an archived version accessible at the DOI: <https://doi.org/10.5281/zenodo.17454878>.

Supplementary information: information on the determination of DFT and DFT+*U* parameters, settings and outputs for machine learning methods, and combined application in a first-principles screening approach for the DFT+*U* parameters. See DOI: <https://doi.org/10.1039/d5dd00292c>.

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